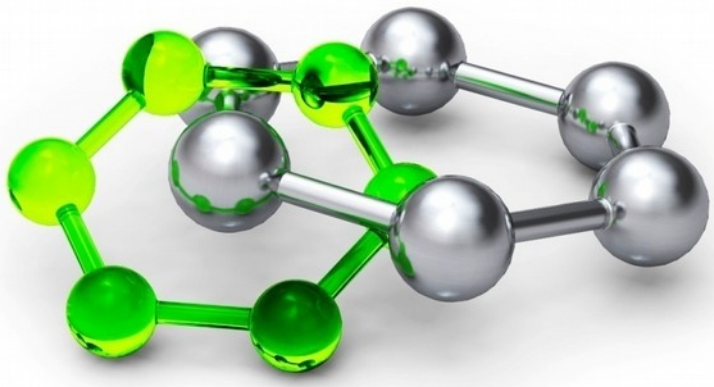
CEITEC

Středoevropský technologický institut

BRNO | ČESKÁ REPUBLIKA

S1007 Doing structural biology with the electron microscope

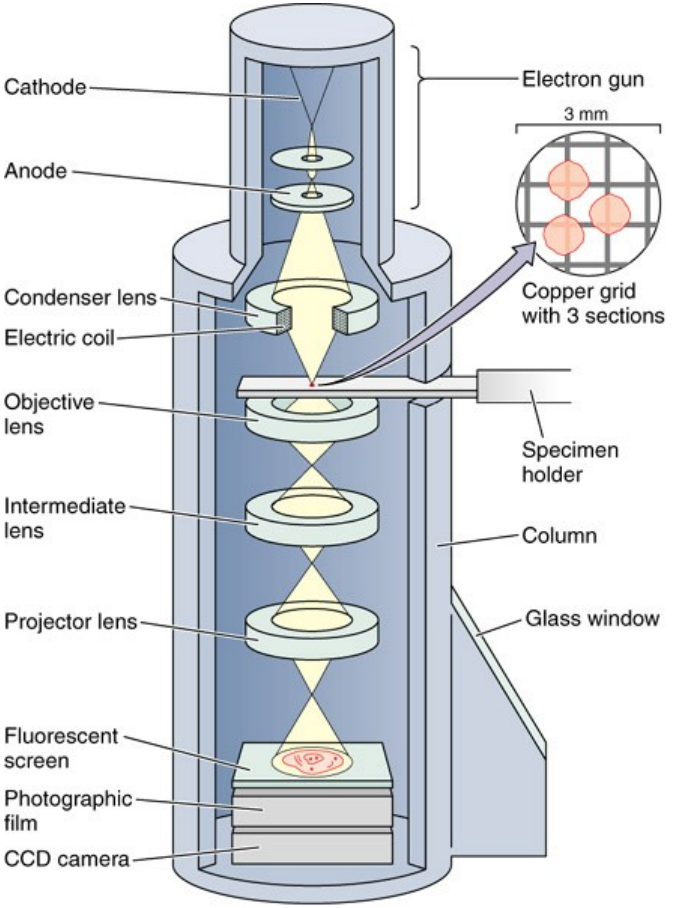
Lecture 3: Electron Microscope



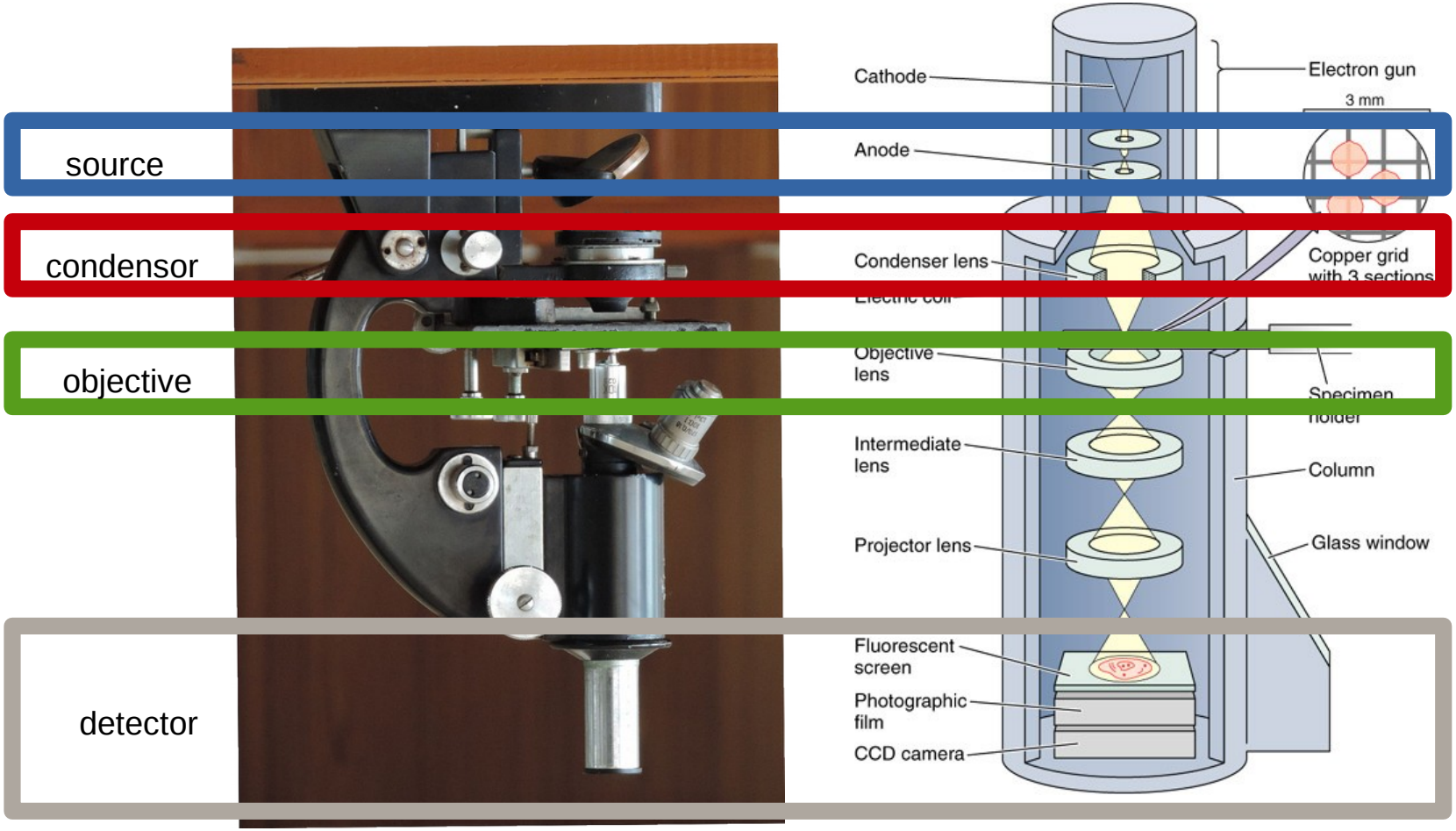
EVROPSKÁ UNIE
EVROPSKÝ FOND PRO REGIONÁLNÍ ROZVOJ
INVESTICE DO VAŠÍ BUDOUCNOSTI

2007–13
OP Výzkum a vývoj pro inovace

Optical vs. TEM microscope



Optical vs. TEM microscope

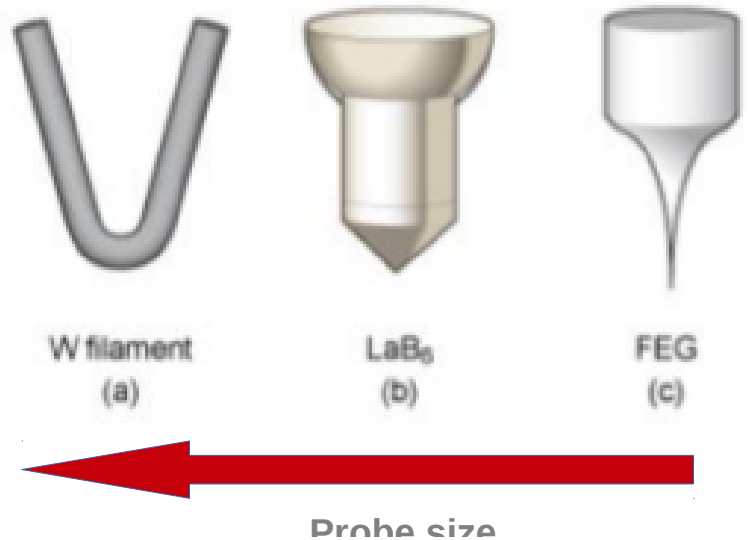


Electron source

- thungsten filament

- LaB6 crystal

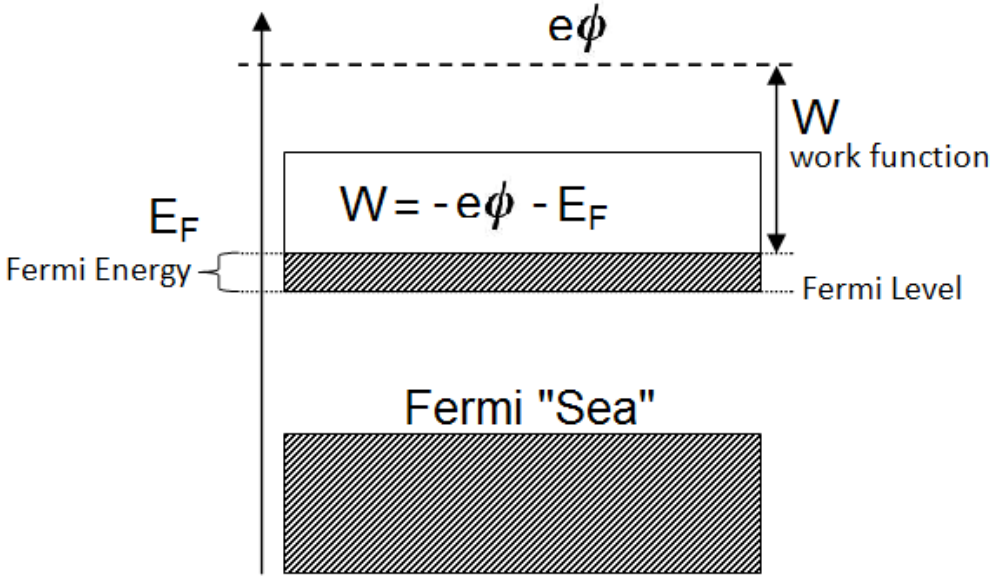
- Field Emission Gun



Work function

$$W = -e\phi - E_F$$

$$\phi = V - \frac{W}{e}$$



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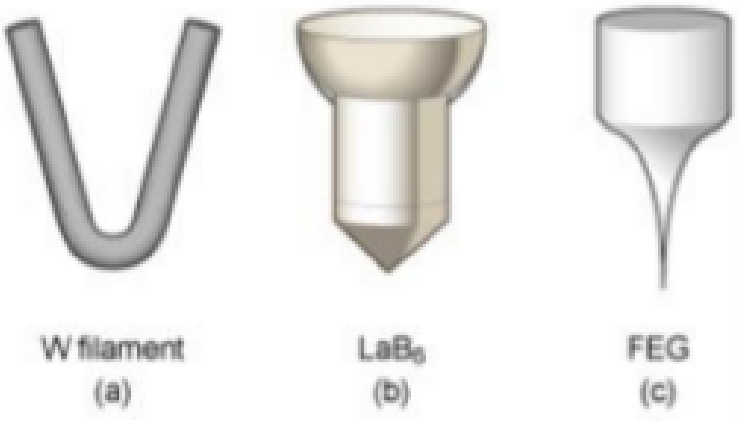
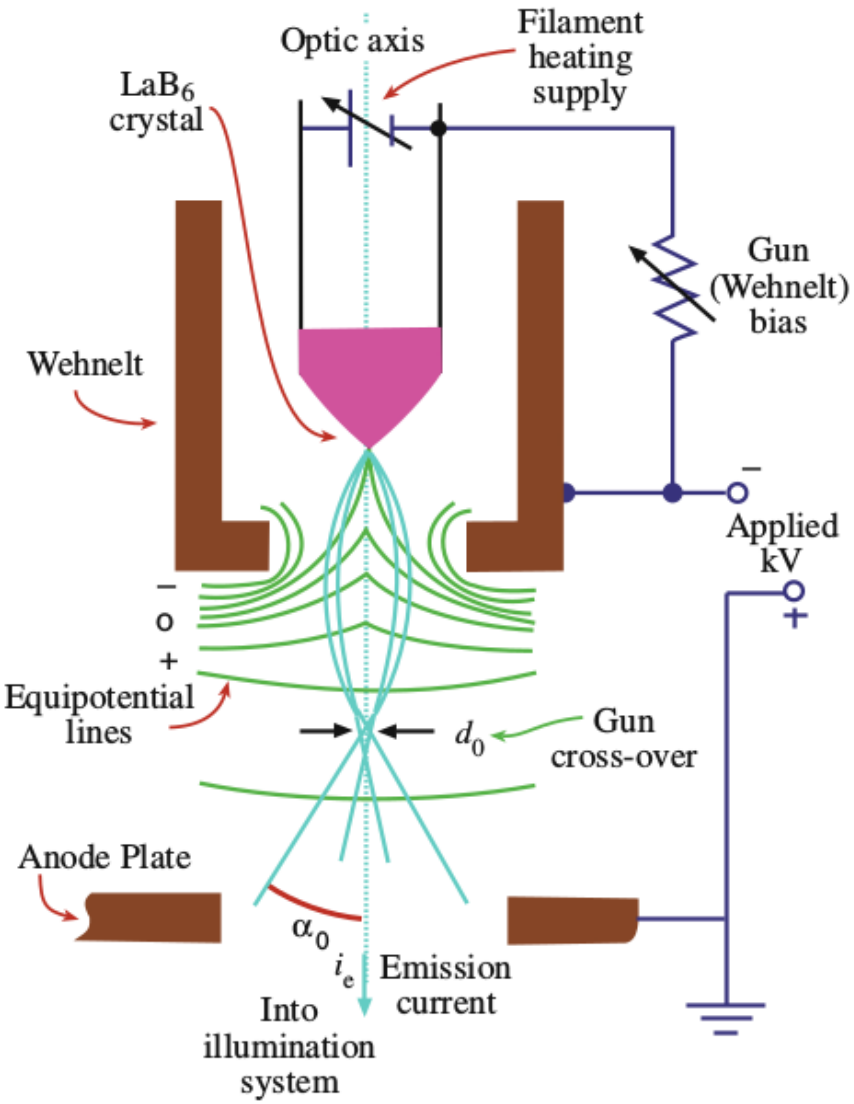
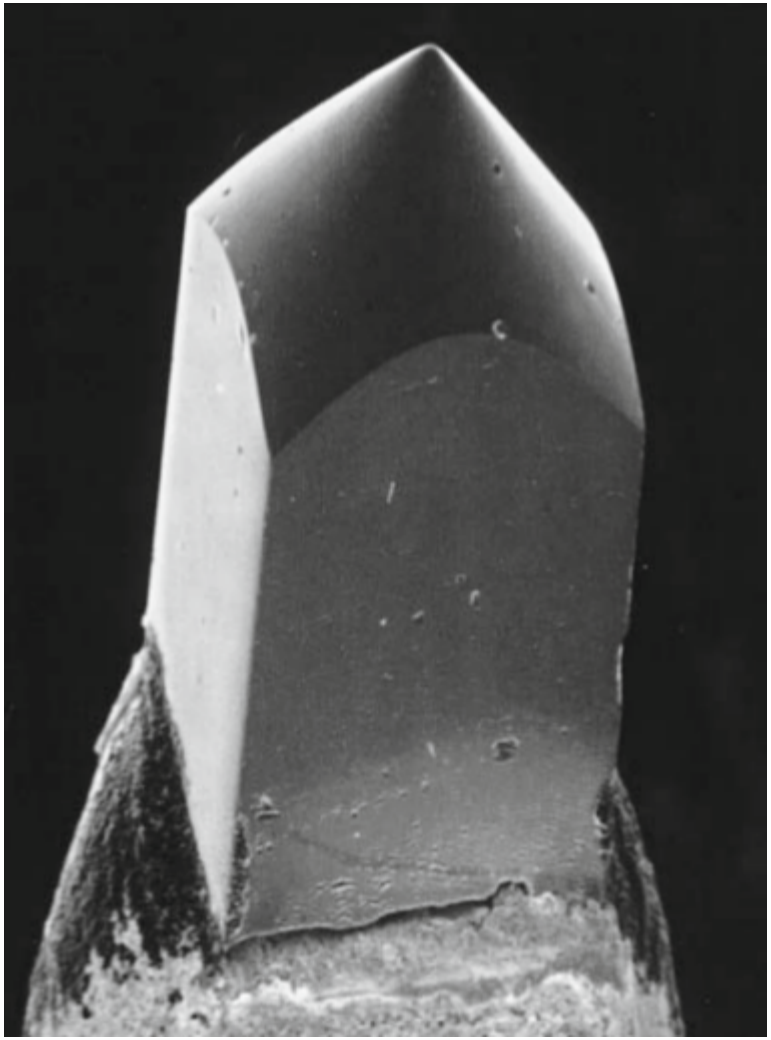


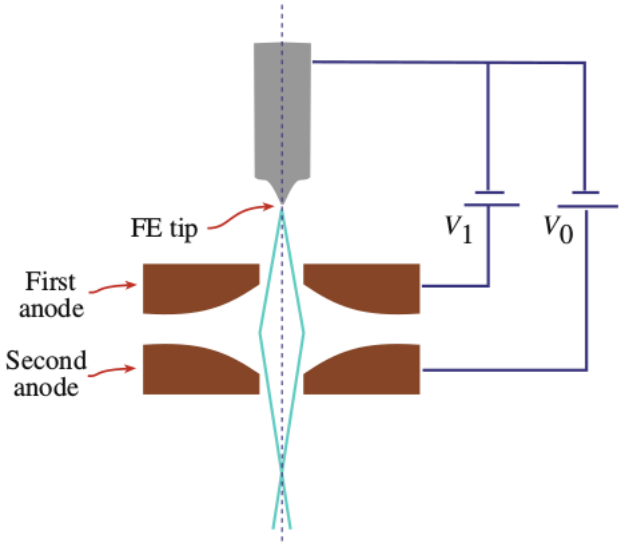
	Units	Tungsten	LaB_6	Schottky FEG	Cold FEG
Work function, Φ	eV	4.5	2.4	3.0	4.5
Richardson's constant	A/m^2K^2	6×10^9	4×10^9		
Operating temperature	K	2700	1700	1700	300
Current density (at 100 kV)	A/m^2	5	10^2	10^5	10^6
Crossover size	nm	$> 10^5$	10^4	15	3
Brightness (at 100 kV)	A/m^2sr	10^{10}	5×10^{11}	5×10^{12}	10^{13}
Energy spread (at 100 kV)	eV	3	1.5	0.7	0.3
Emission current stability	%/hr	<1	<1	<1	5
Vacuum	Pa	10^{-2}	10^{-4}	10^{-6}	10^{-9}
Lifetime	hr	100	1000	>5000	>5000

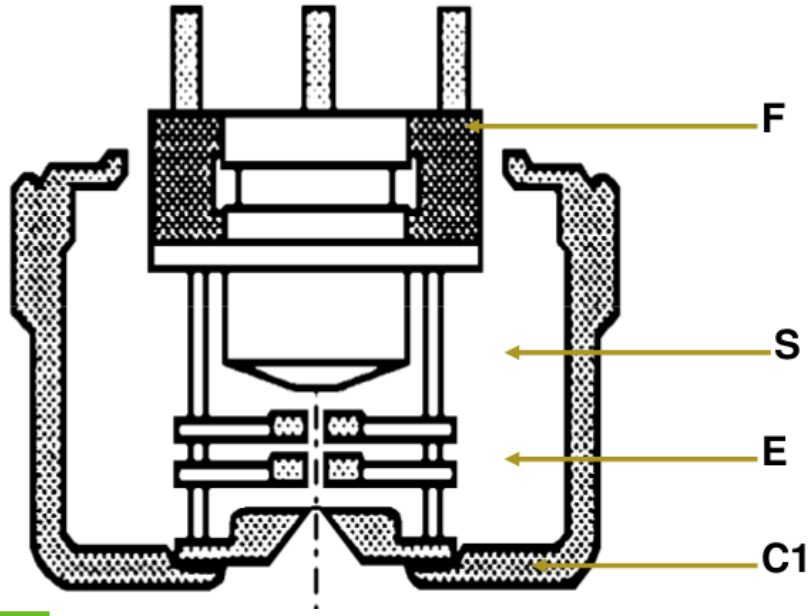
Electron source - LaB6

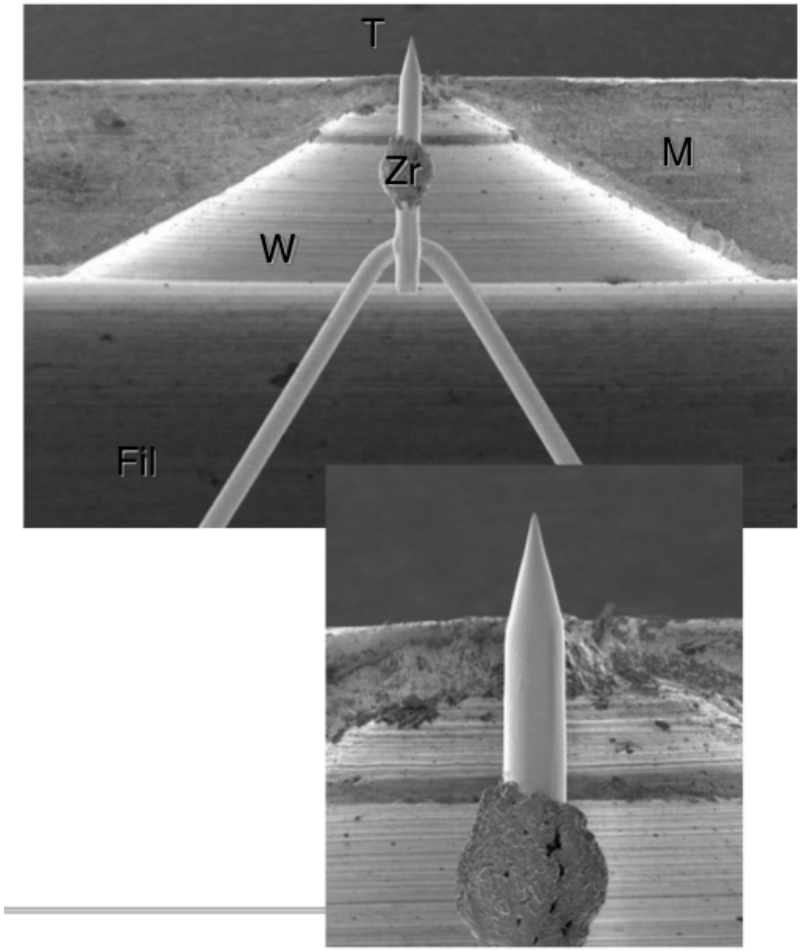




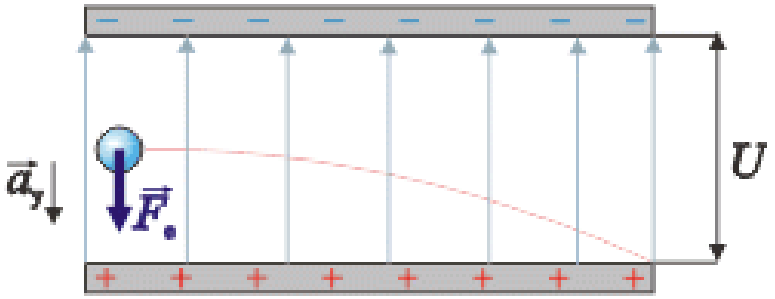
Electron source - FEG







Electron source - accelerator



E=U.e

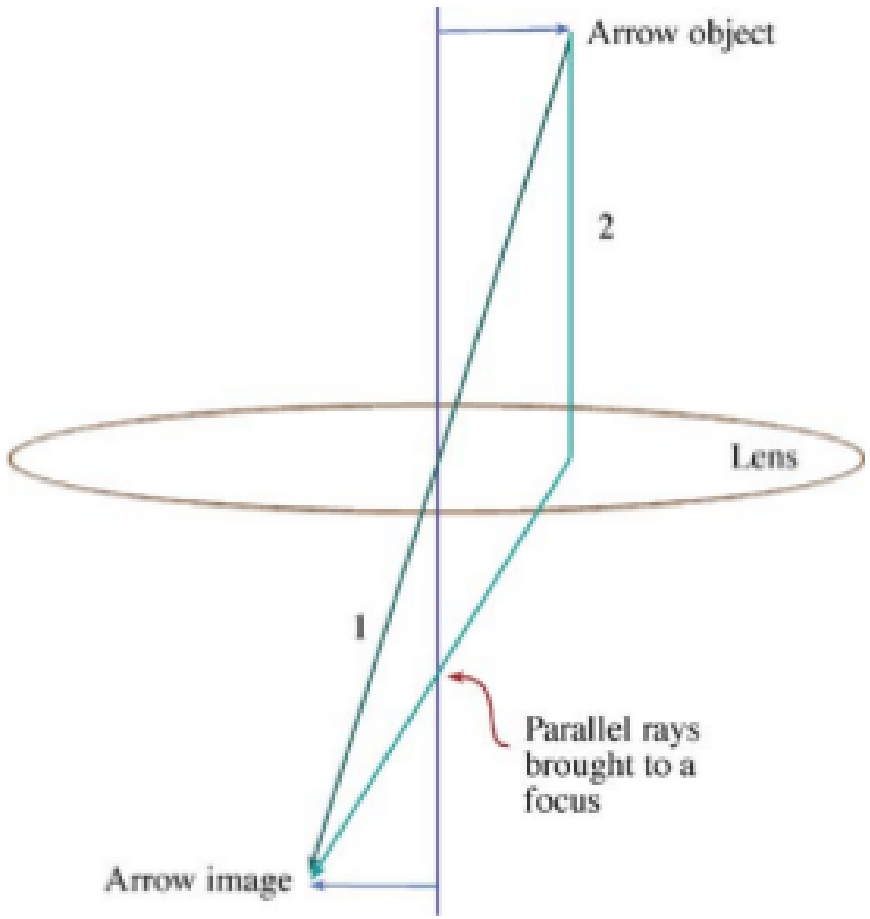
$$E_k = \frac{1}{2}mv^2 \qquad E_k = \frac{p^2}{2m}$$

U=300kV => λ=1.97pm
U=200kV ??

Electron source - accelerator

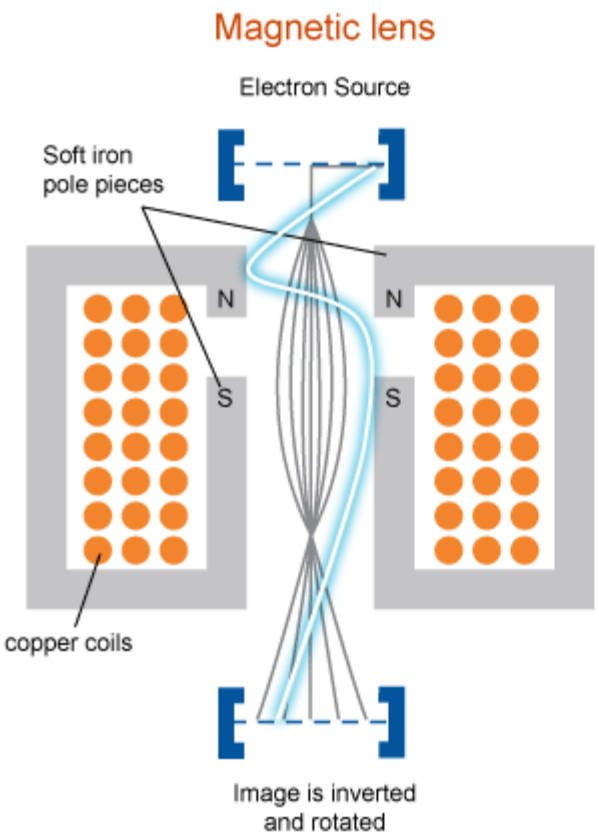
Task 1: What is the electron wavelength at acceleration voltage of 200kV?

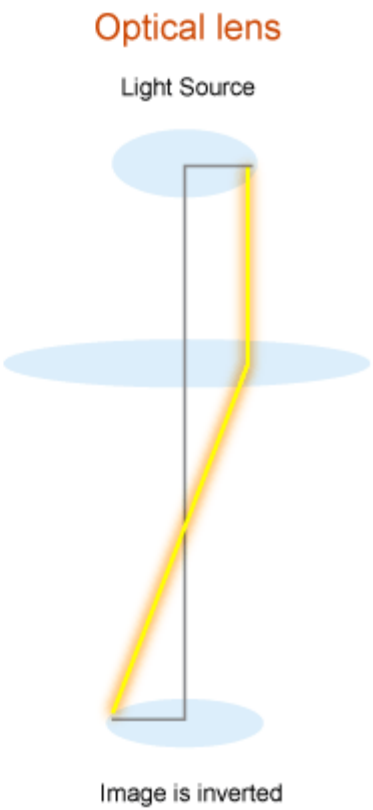
Lenses – ray diagram

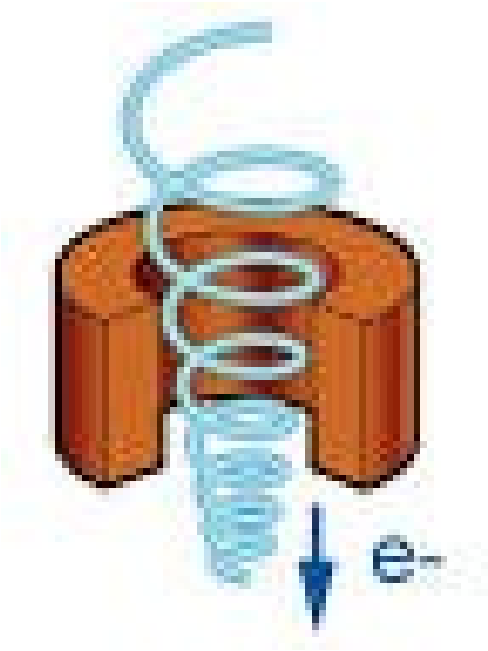


Electromagnetic lenses

Lorentz force: $\mathbf{F} = q(\mathbf{E} + \mathbf{v} \times \mathbf{B})$

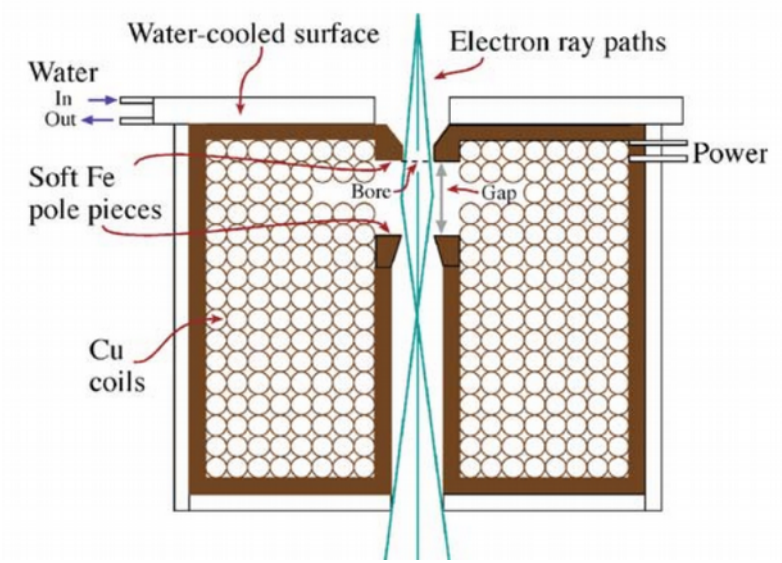


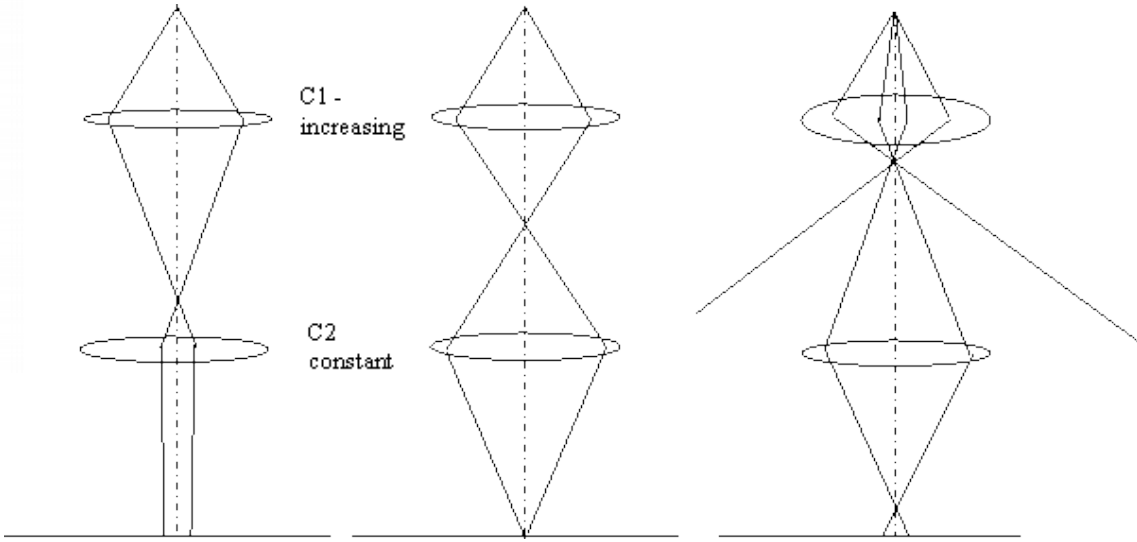




Magnetic lenses rotate image

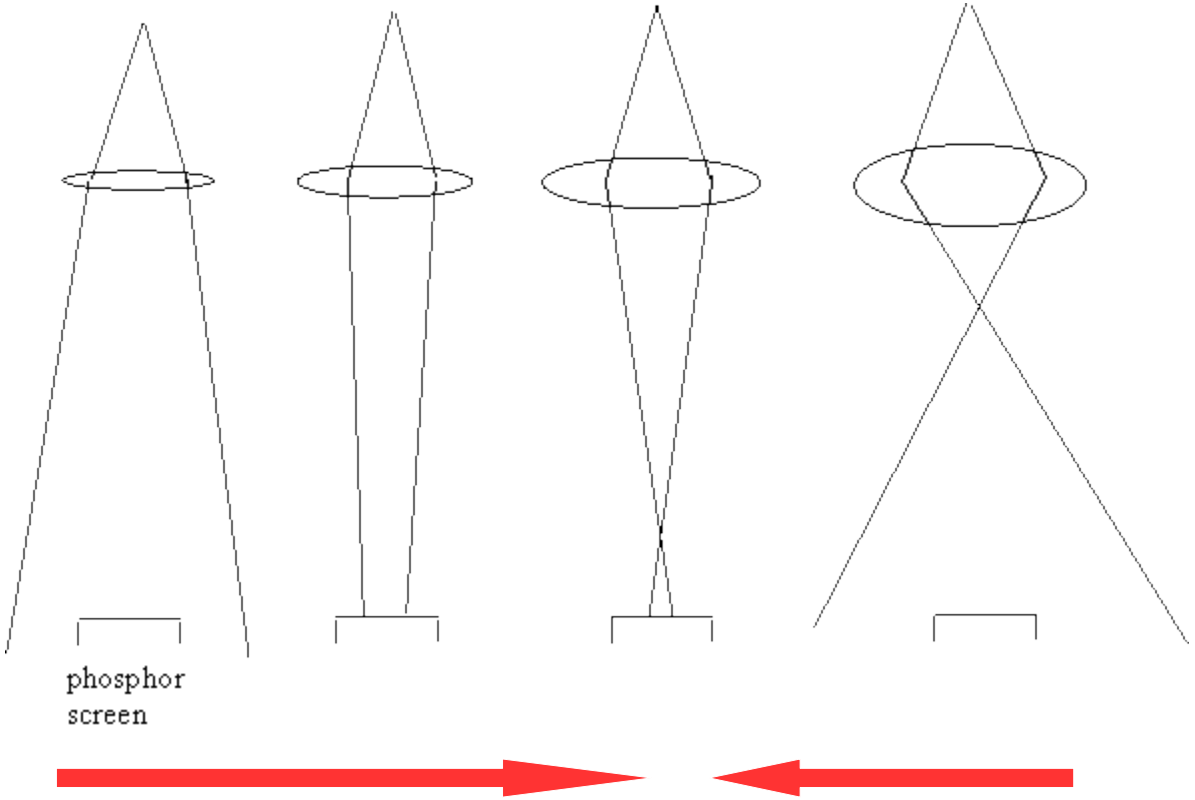
Electromagnetic lenses





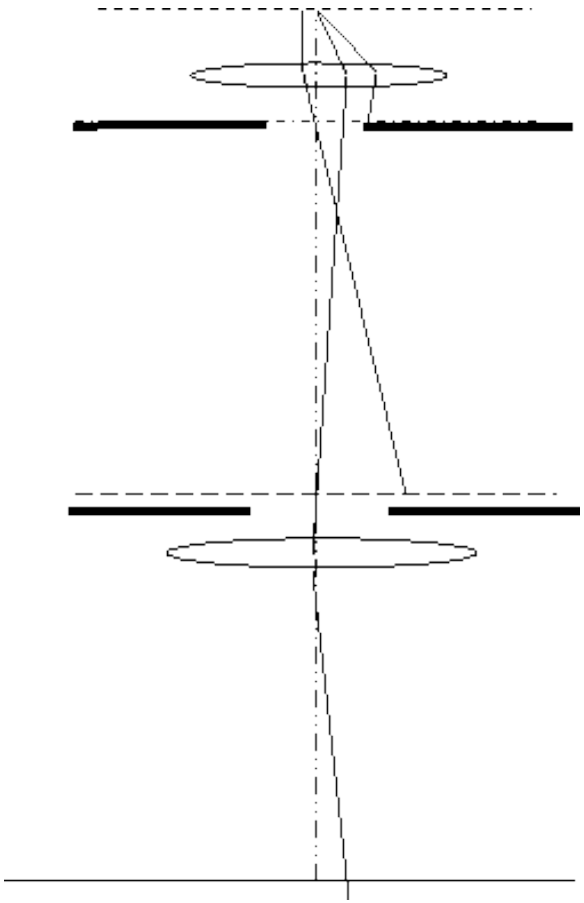
Power of the magnetic lens can be changed

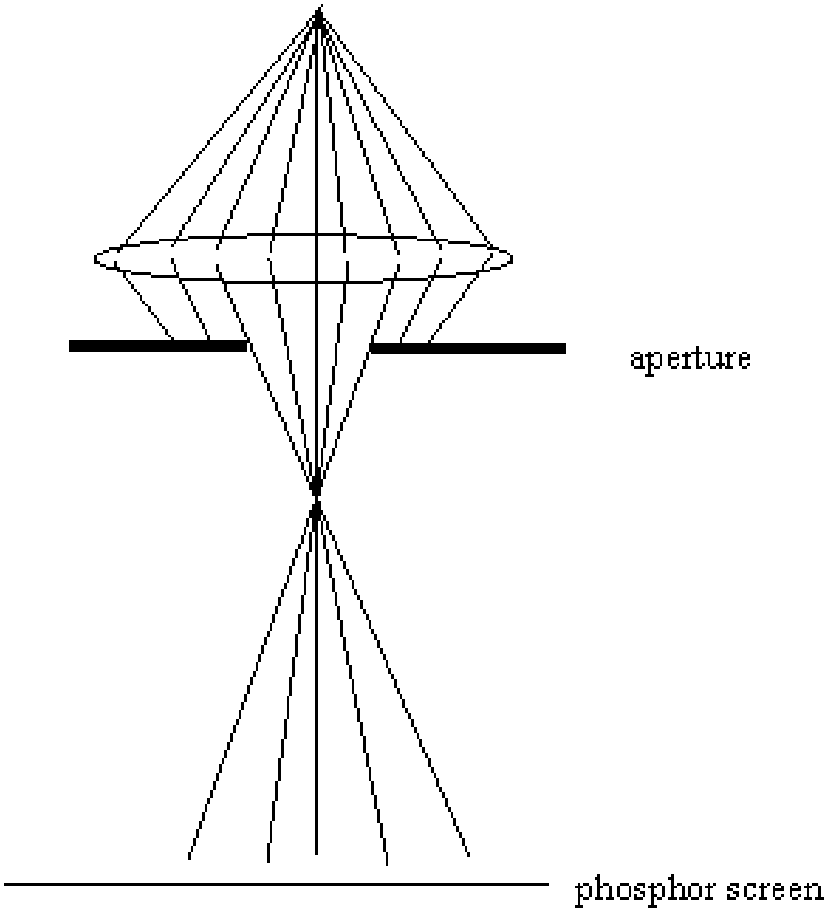
Electromagnetic lenses



Illumination on the detector changes with change of lens power

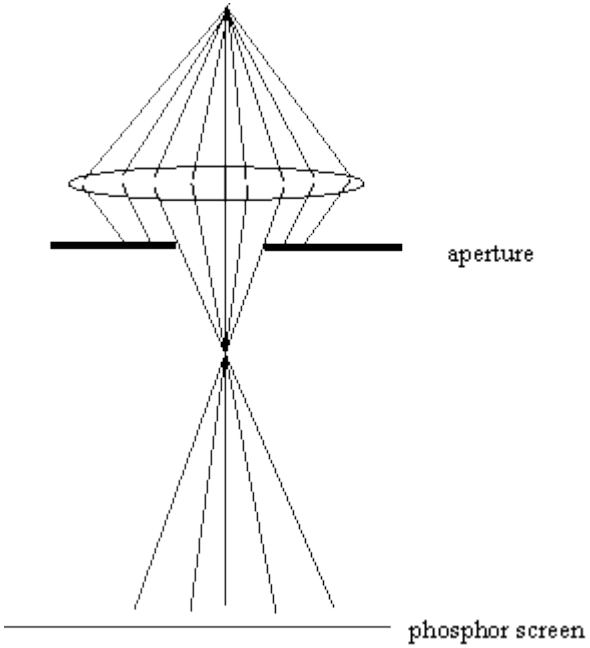
Lens assembly - appertures

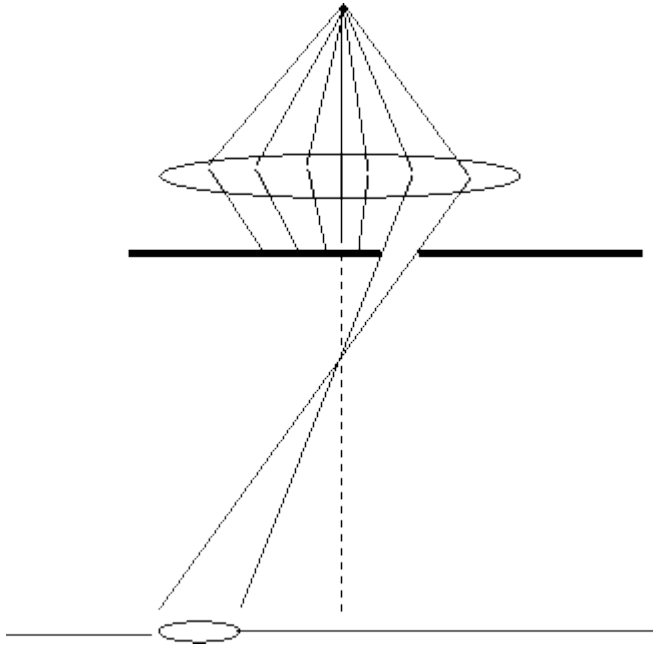




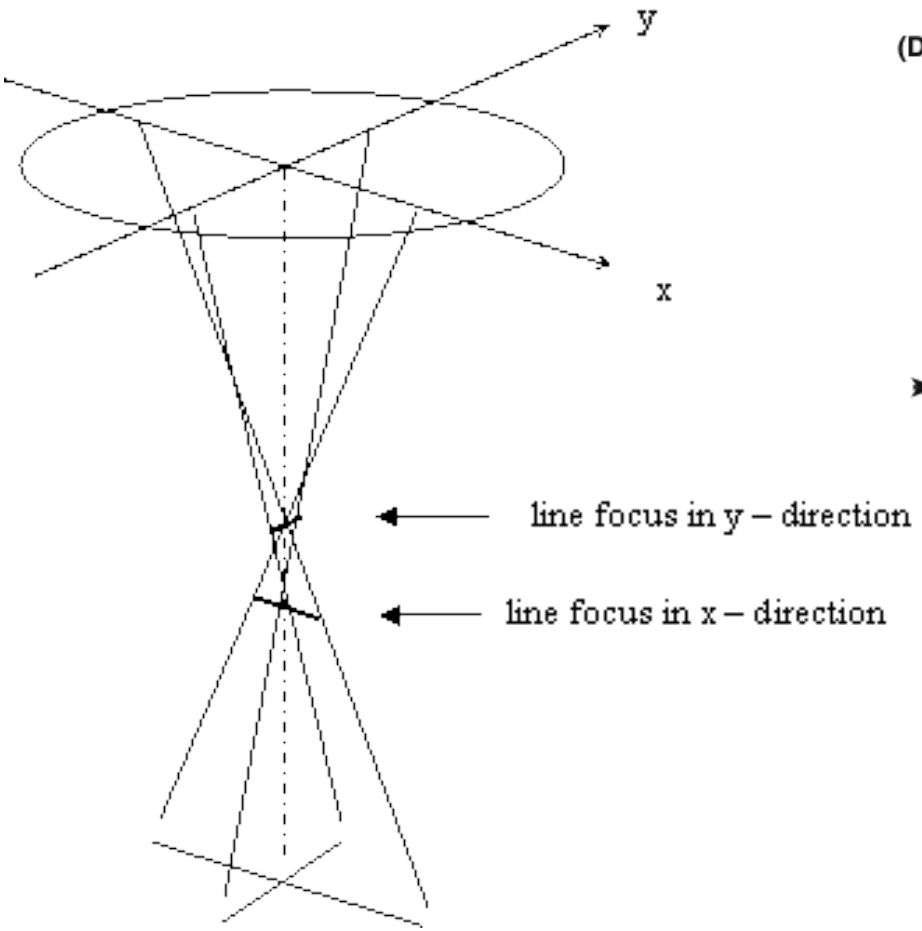
Apperture size: ~100um

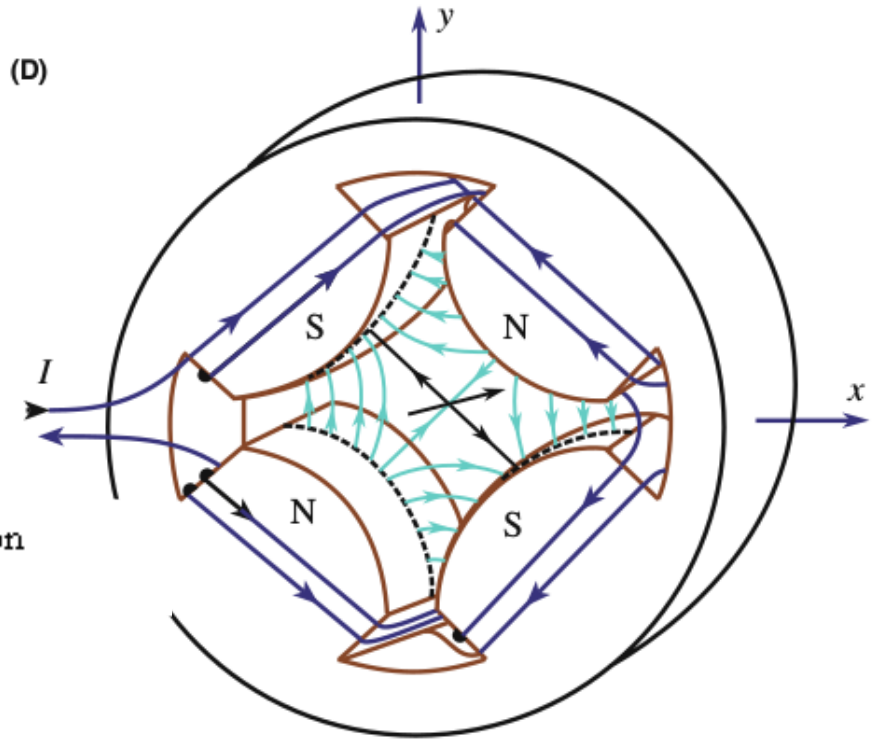
Lens assembly - appertures



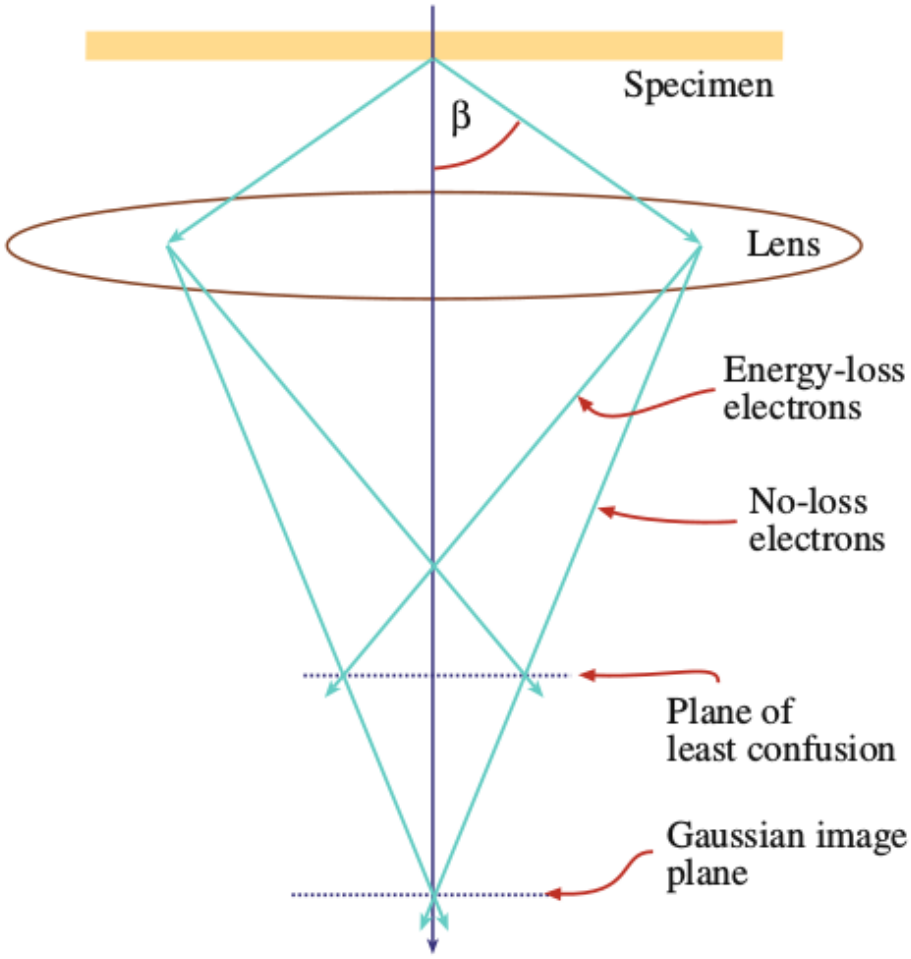


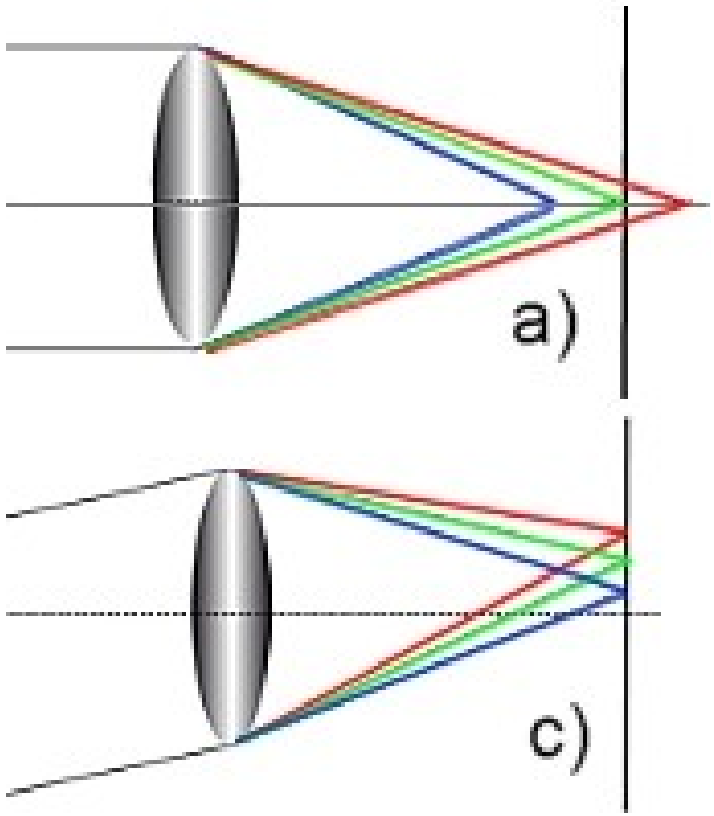
Lens assembly - stigmators



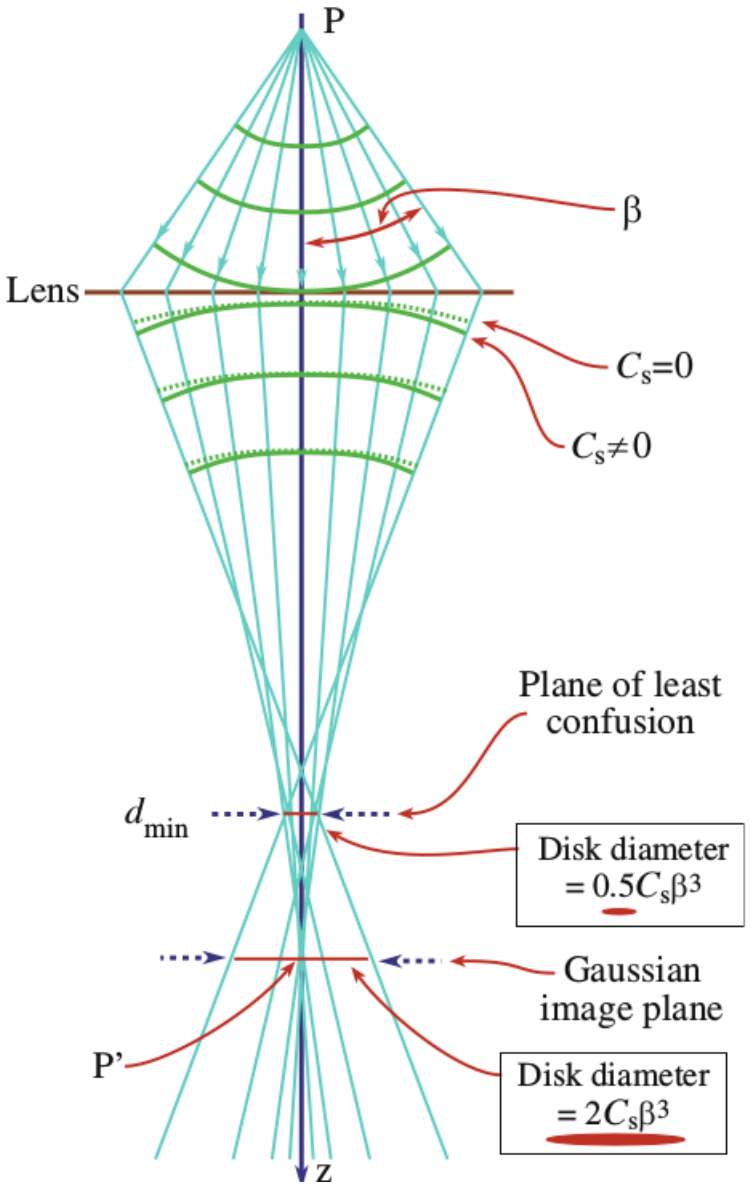


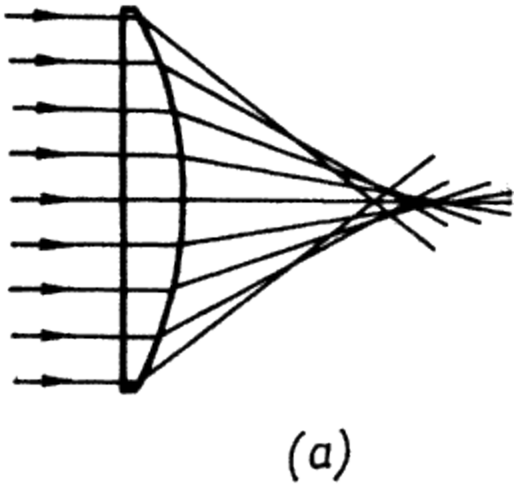
Lens aberrations - chromatic



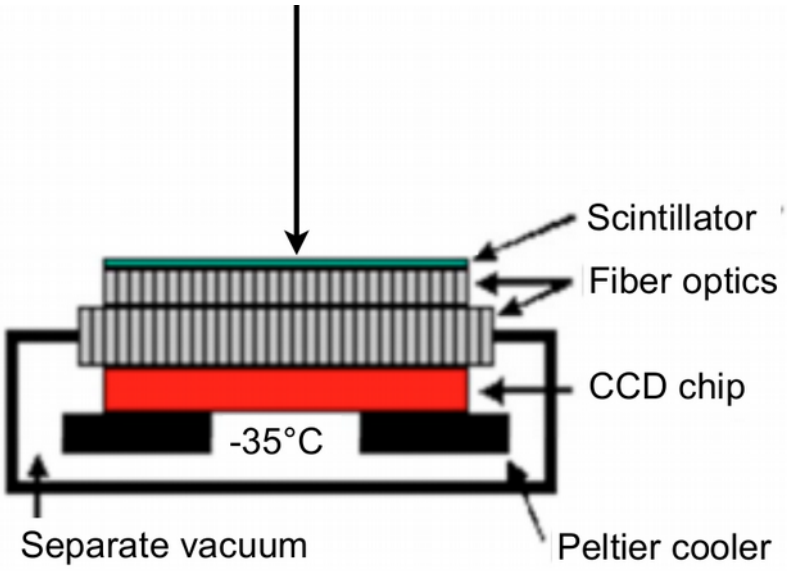


Lens aberrations - spherical

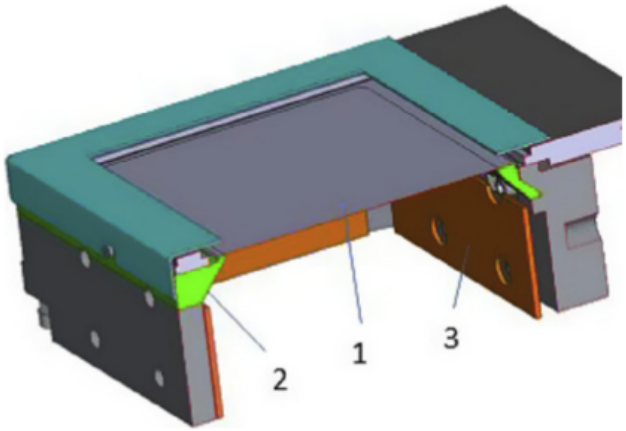


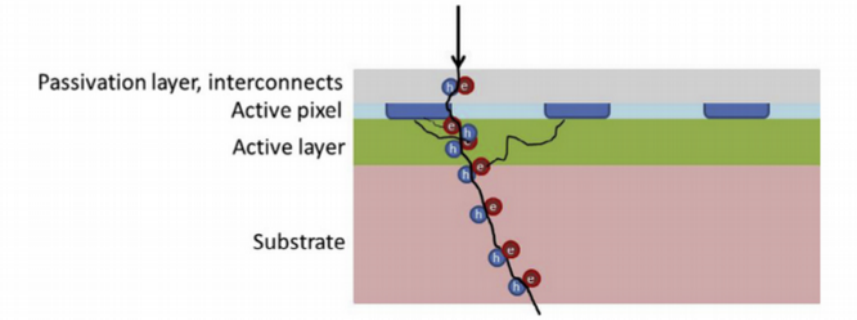


Detectors



CCD – charge coupled device





CMOS – complementary metal oxide semiconductor

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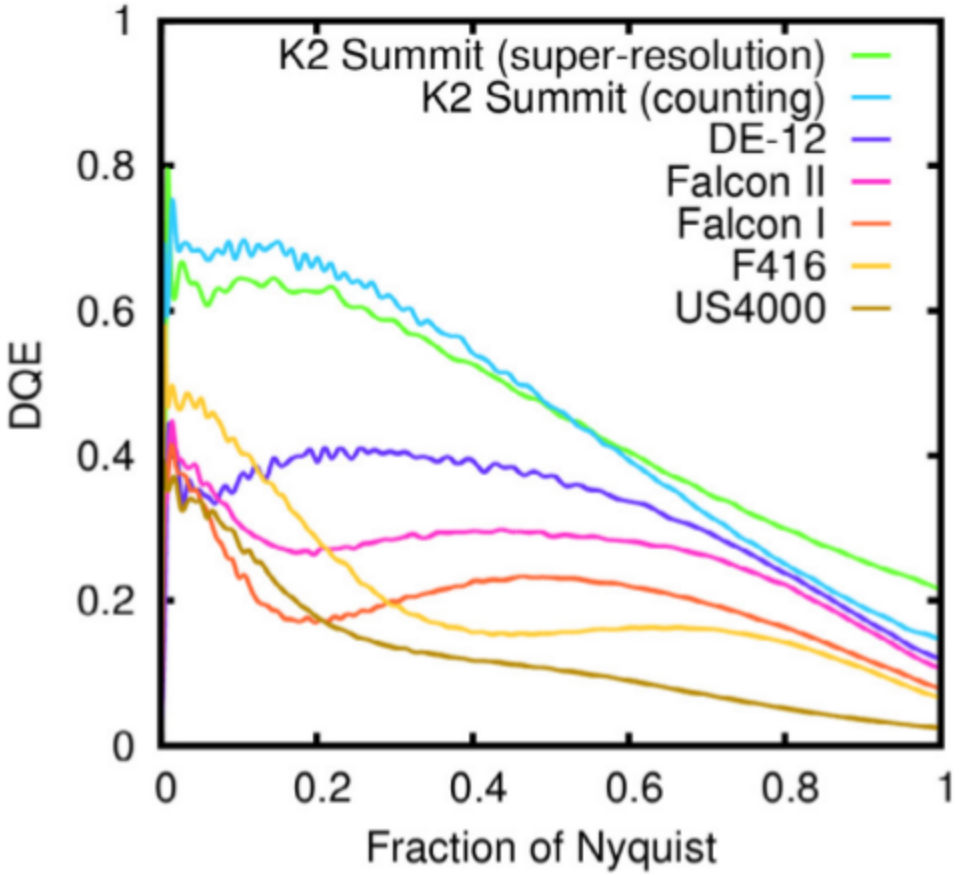
Detectors

DQE – detective quantum efficiency



- probability to detect an electron

- DQE ~ sin(x)/x

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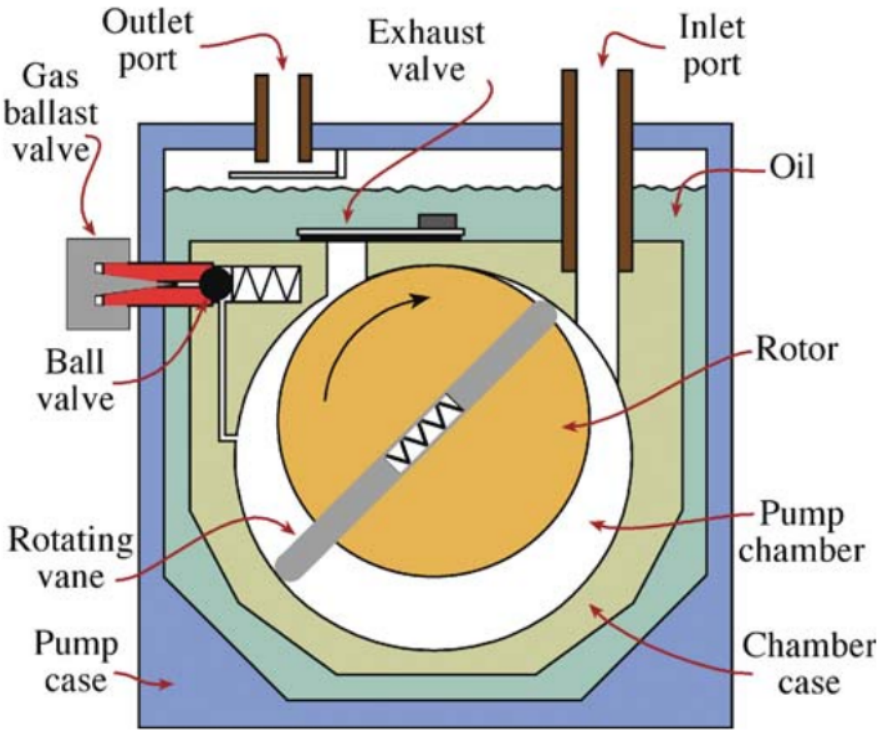
Vacuum system

- roughing pump (10^{5} – 10^{-4} Pa)

- turbo molecular pump (10^{-2} – 10^{-8}Pa)

- ion getter pump (up to 10^{-9}Pa)



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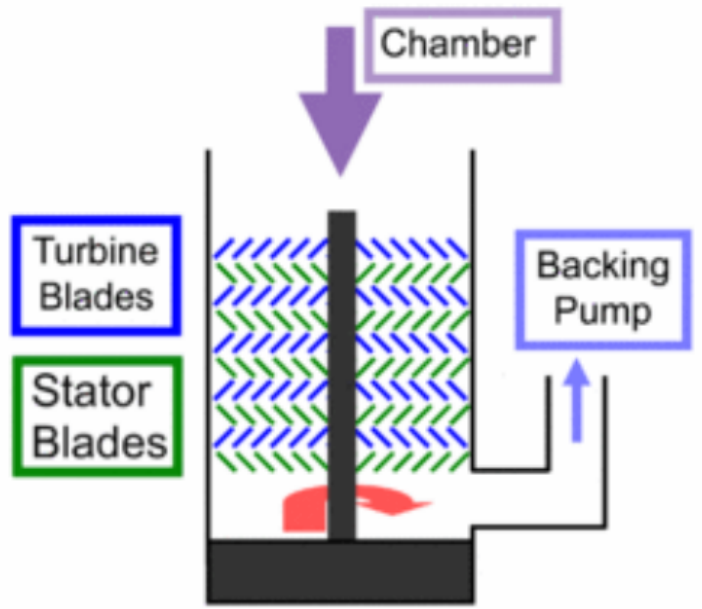

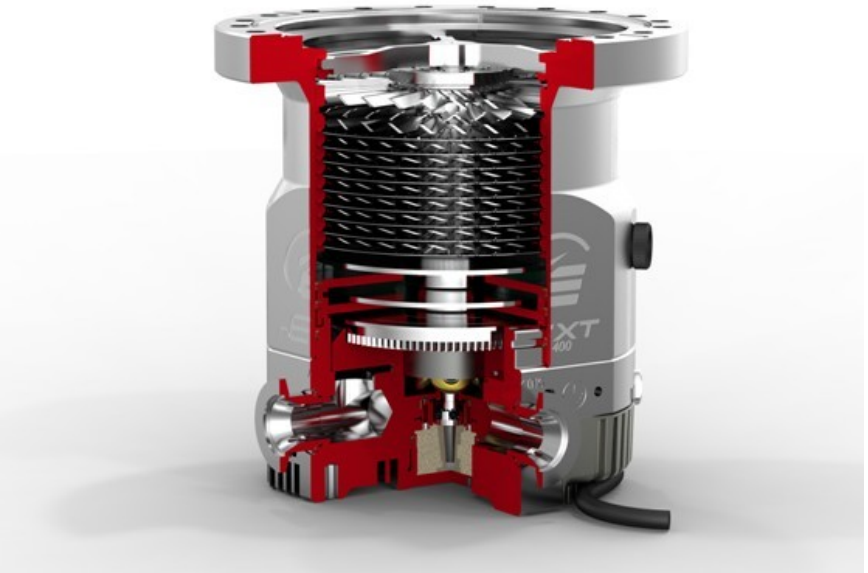

90.000 rpm

Vacuum system

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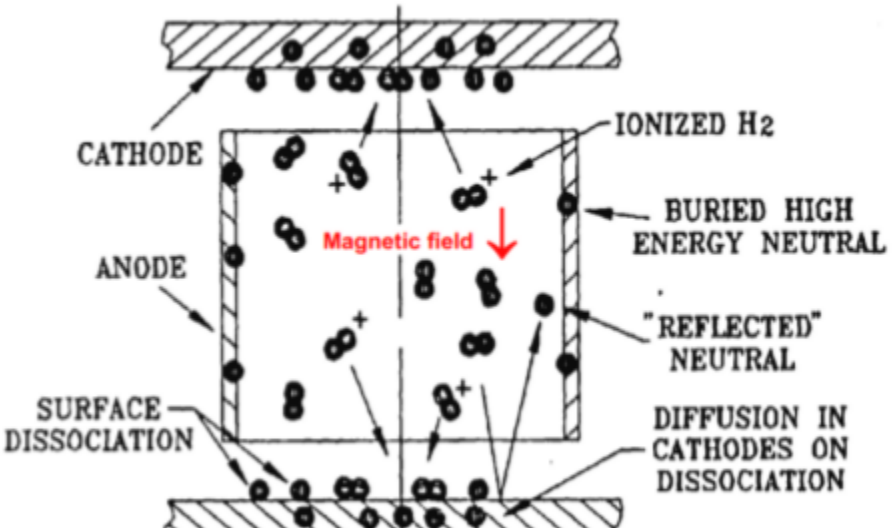
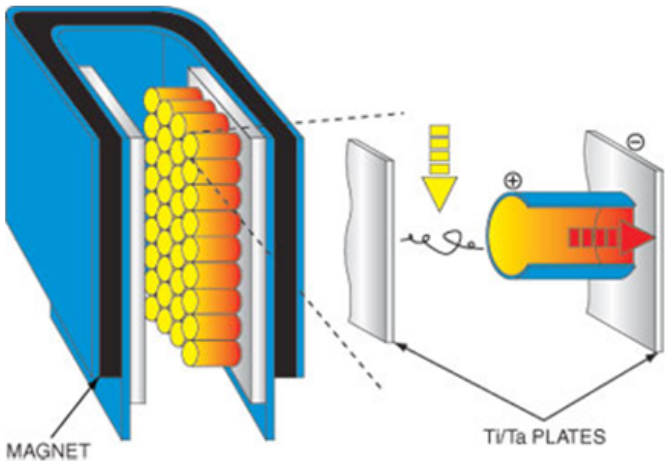
- turbo molecular pump (10^{-2} – 10^{-8}Pa)
- ion getter pump (up to 10^{-9}Pa)

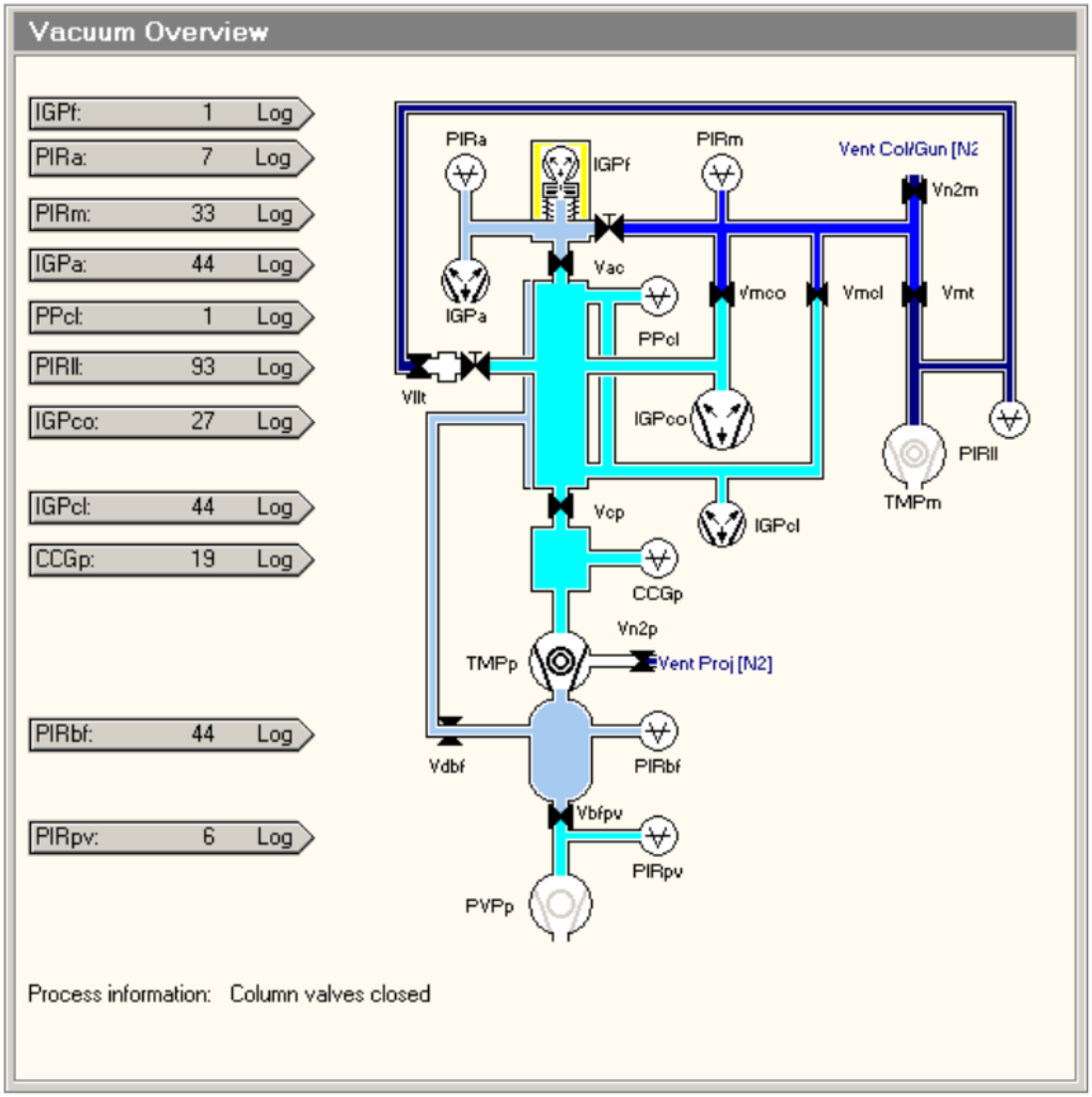




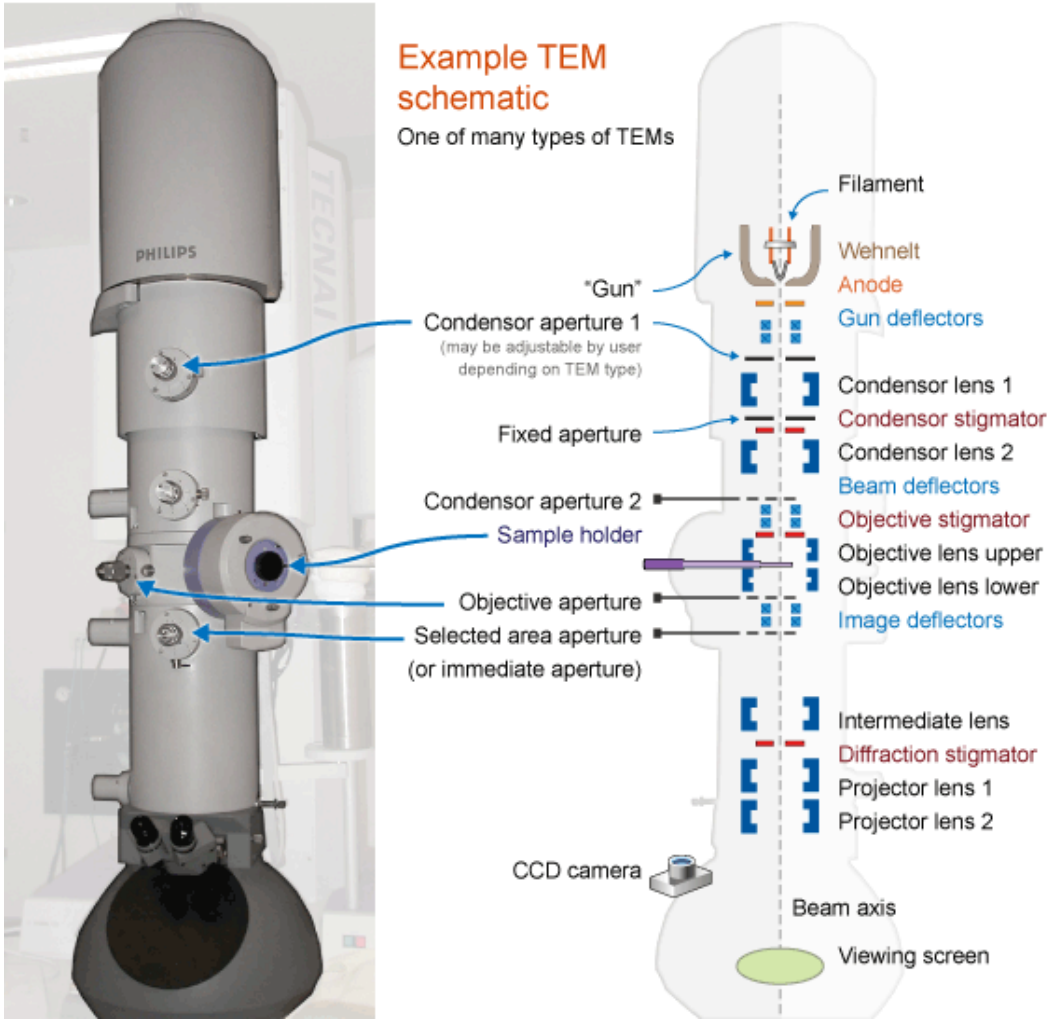
Principle of Operation

External View

Vacuum system



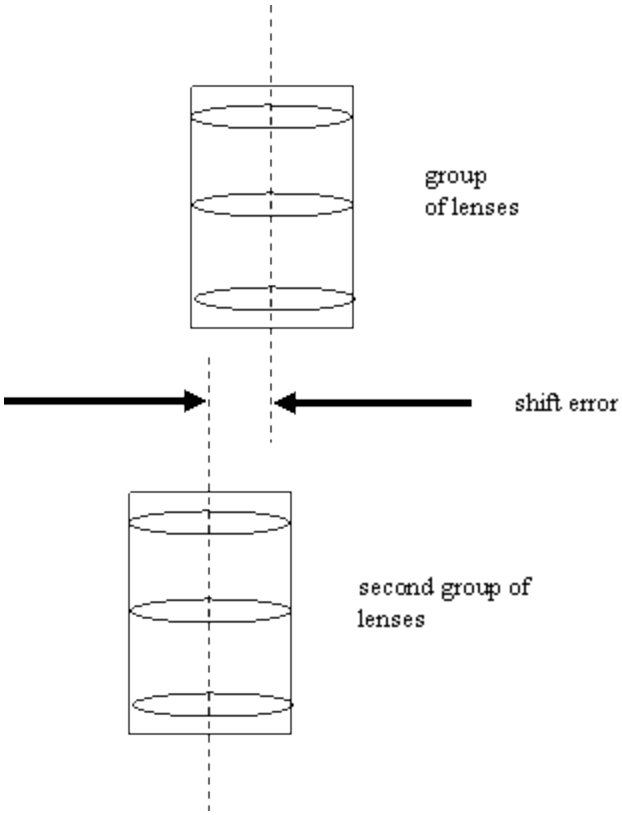
TEM

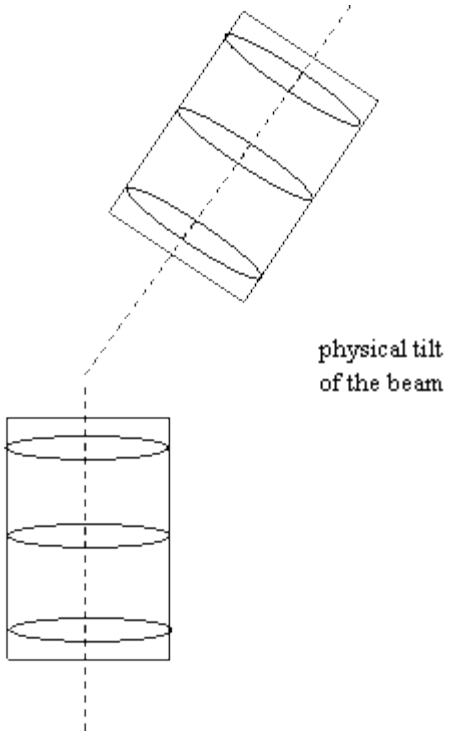

PHILIPS
Example TEM schematic
One of many types of TEMs
Filament
Wehnelt
Anode
"Gun"
Gun deflectors
Condensor aperture 1
(may be adjustable by user depending on TEM type)
Condensor lens 1
Condensor stigmator
Fixed aperture
Condensor lens 2
Beam deflectors
Condensor aperture 2
Objective stigmator
Sample holder
Objective lens upper
Objective lens lower
Objective aperture
Image deflectors
Selected area aperture
(or immediate aperture)
Intermediate lens
Diffraction stigmator
Projector lens 1
Projector lens 2
CCD camera
Beam axis
Viewing screen

TEM

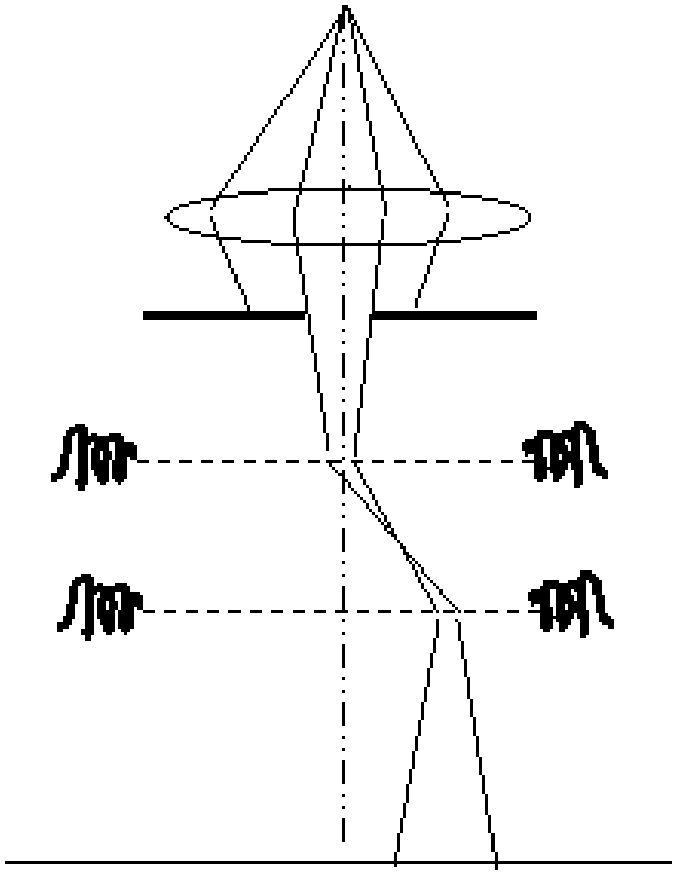
Task 2: How many electron are there in the microscope at one point? (U=300kV, I=1nA, column length: 2m)

TEM


group
of lenses
shift error
second group of
lenses

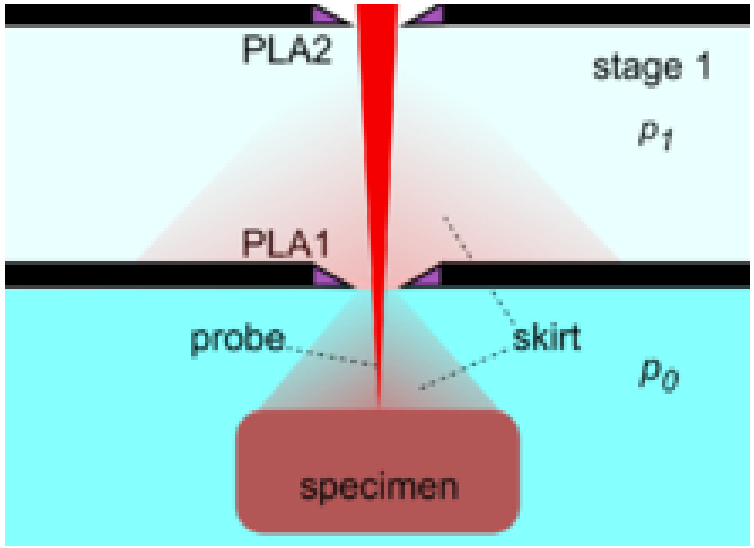

physical tilt
of the beam

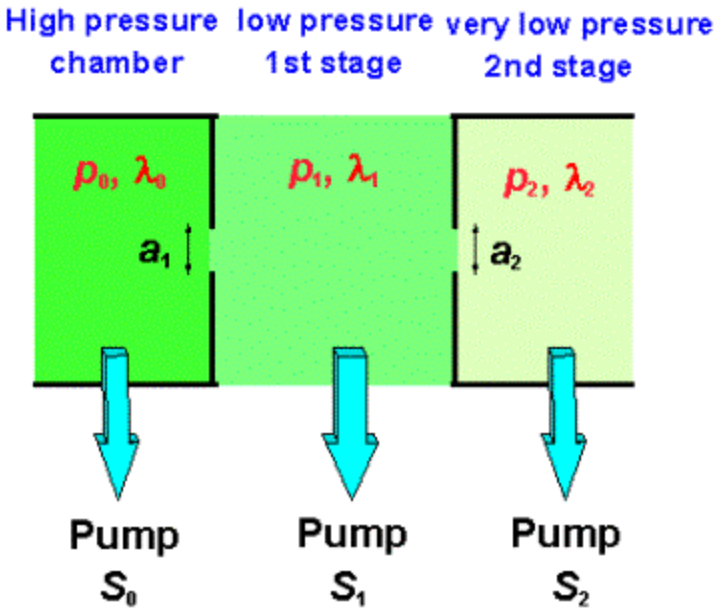
TEM



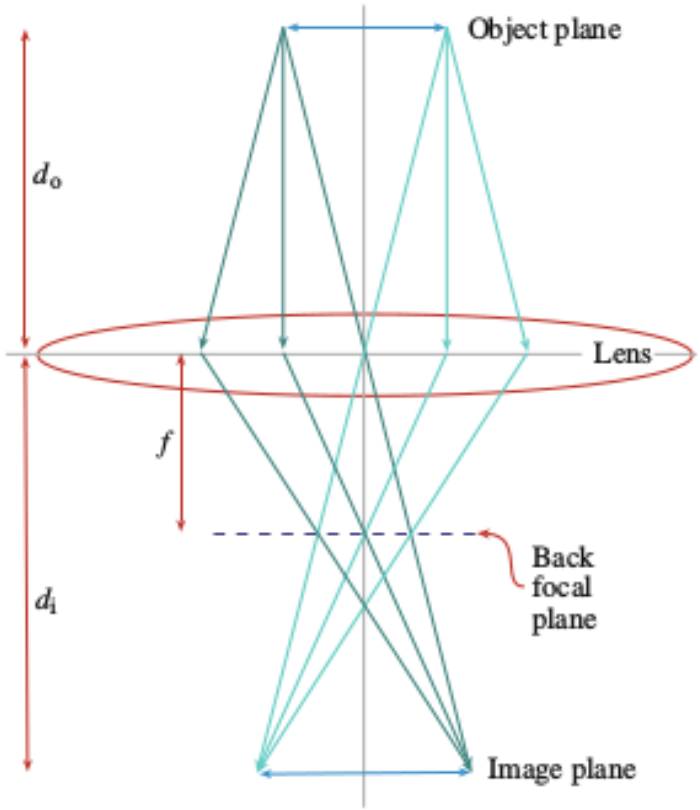
TEM

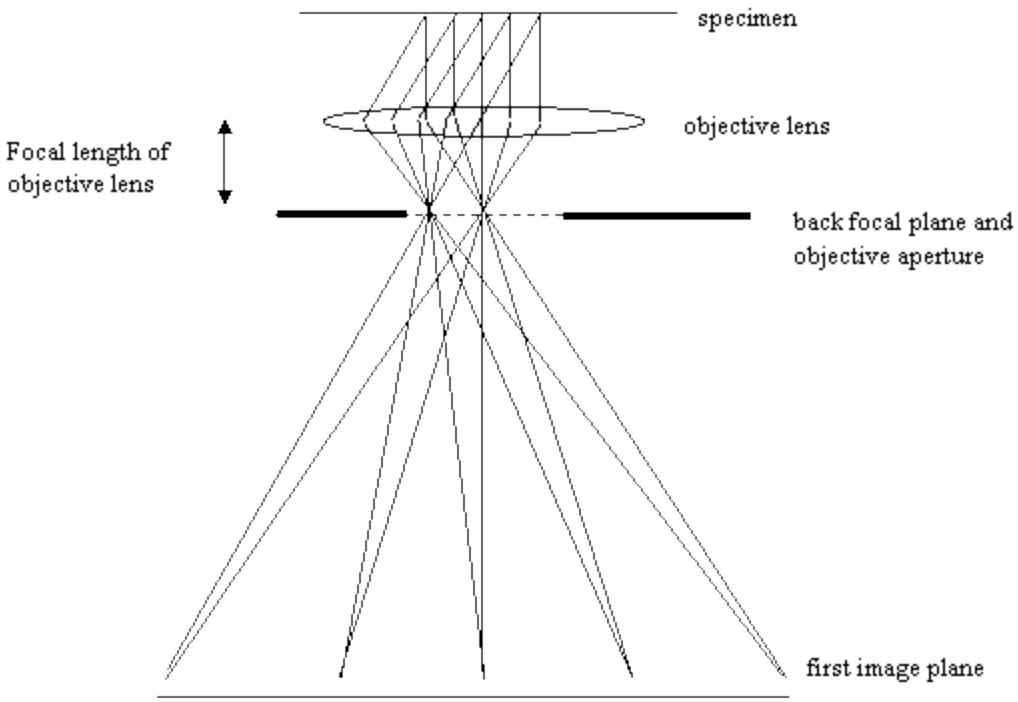
Differential pumping apperture



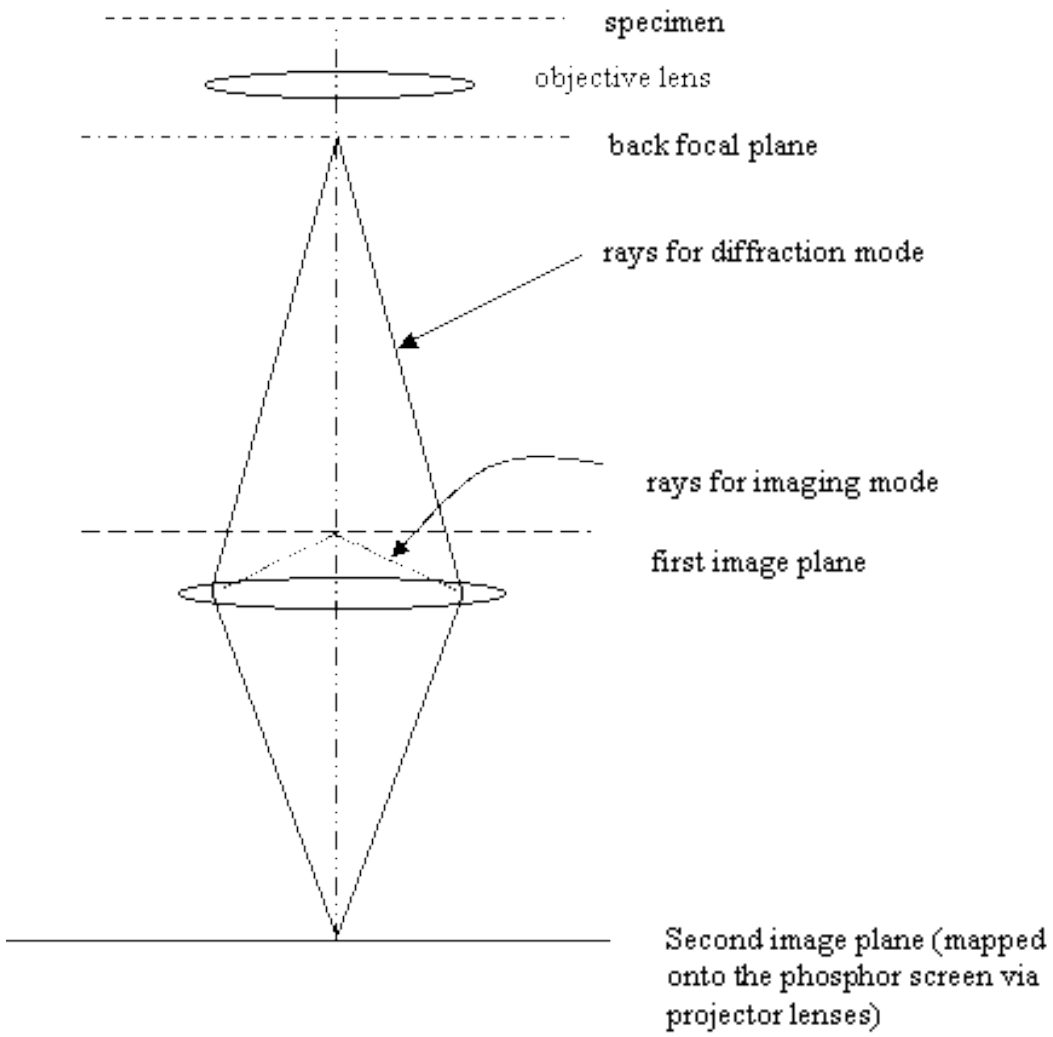


TEM

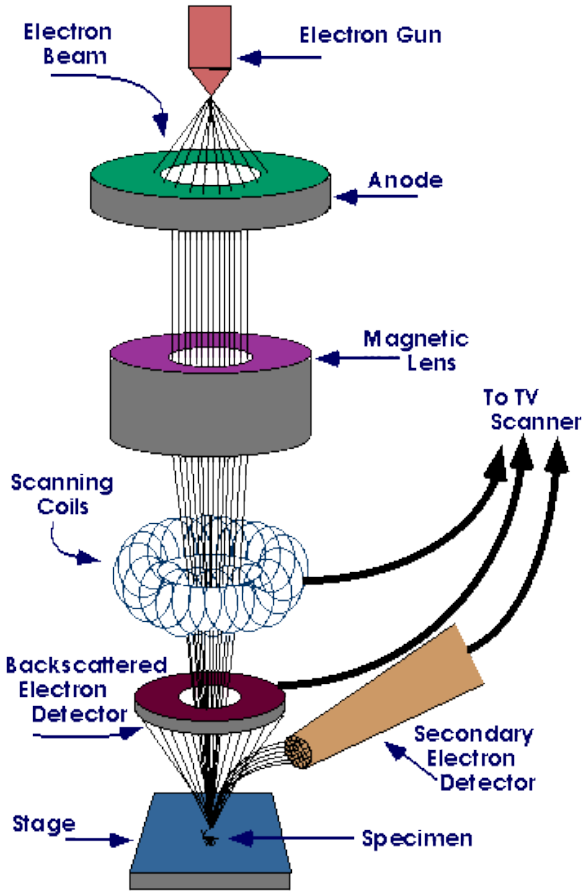

Object plane
d_o
Lens
f
d_i
Back
focal
plane
Image plane

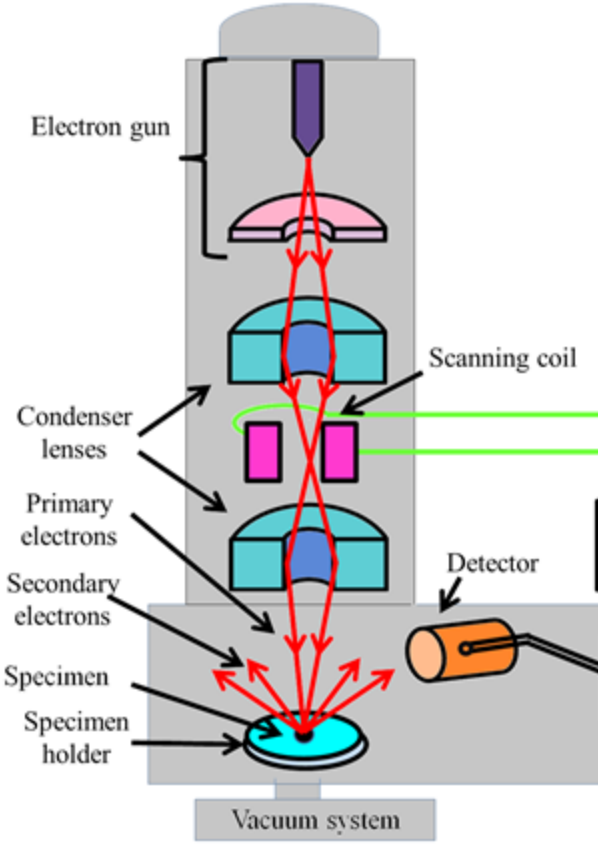

specimen
objective lens
Focal length of
objective lens
back focal plane and
objective aperture
first image plane

TEM


specimen
objective lens
back focal plane
rays for diffraction mode
rays for imaging mode
first image plane
Second image plane (mapped onto the phosphor screen via projector lenses)

SEM

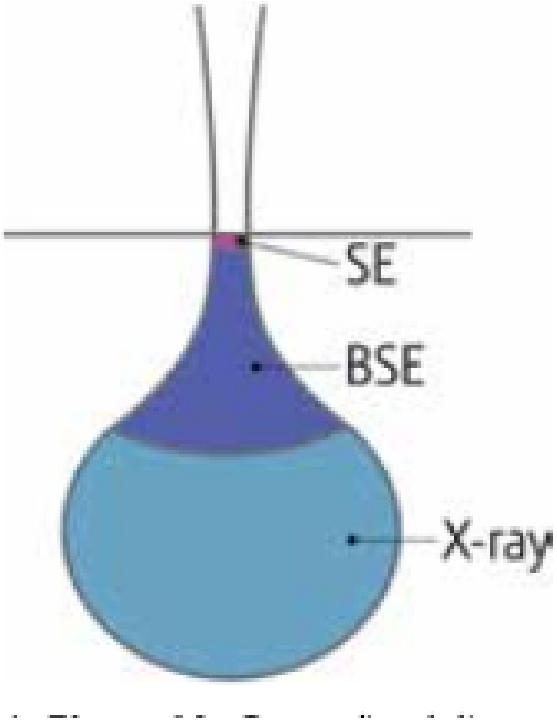

Electron Beam
Electron Gun
Anode
Magnetic Lens
To TV Scanner
Scanning Coils
Backscattered Electron Detector
Secondary Electron Detector
Stage
Specimen

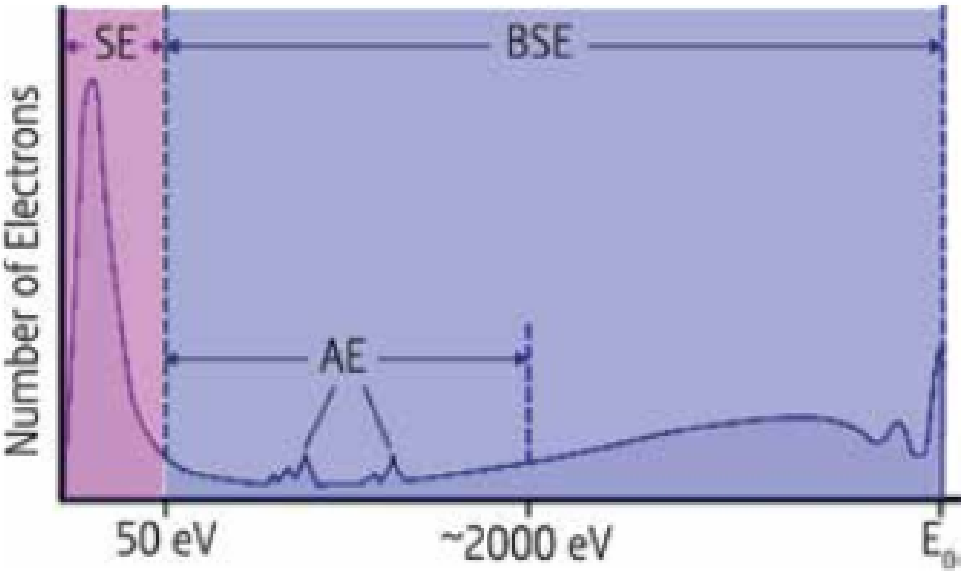

Electron gun
Scanning coil
Condenser lenses
Primary electrons
Detector
Secondary electrons
Specimen
Specimen holder
Vacuum system

SEM

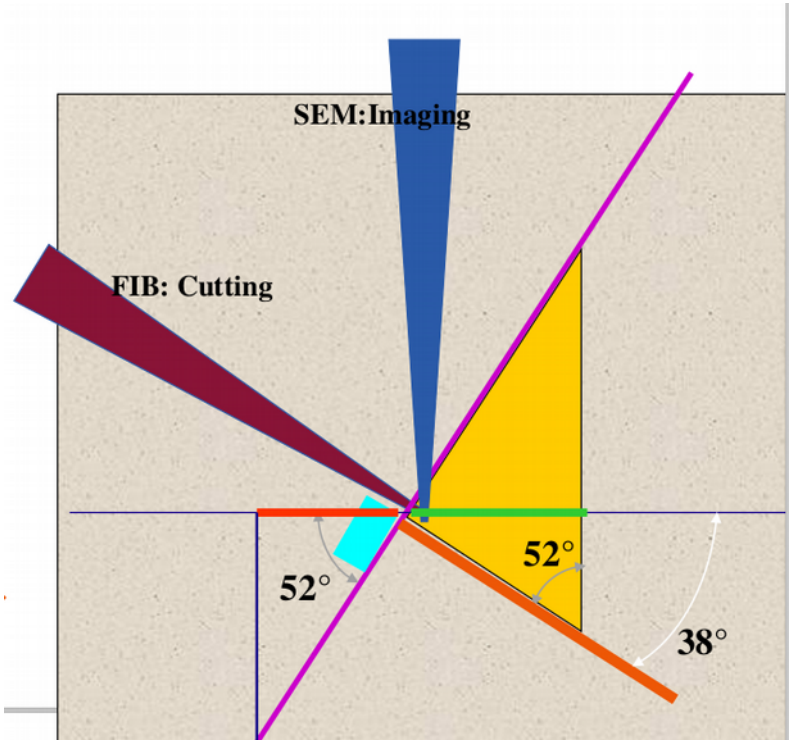
Task 3: What is the radiation damage (electron dose in e-/A2) of the specimen in SEM?
(U=2kV, I=5pA, dwell time: 1us, spot size: 5nm)

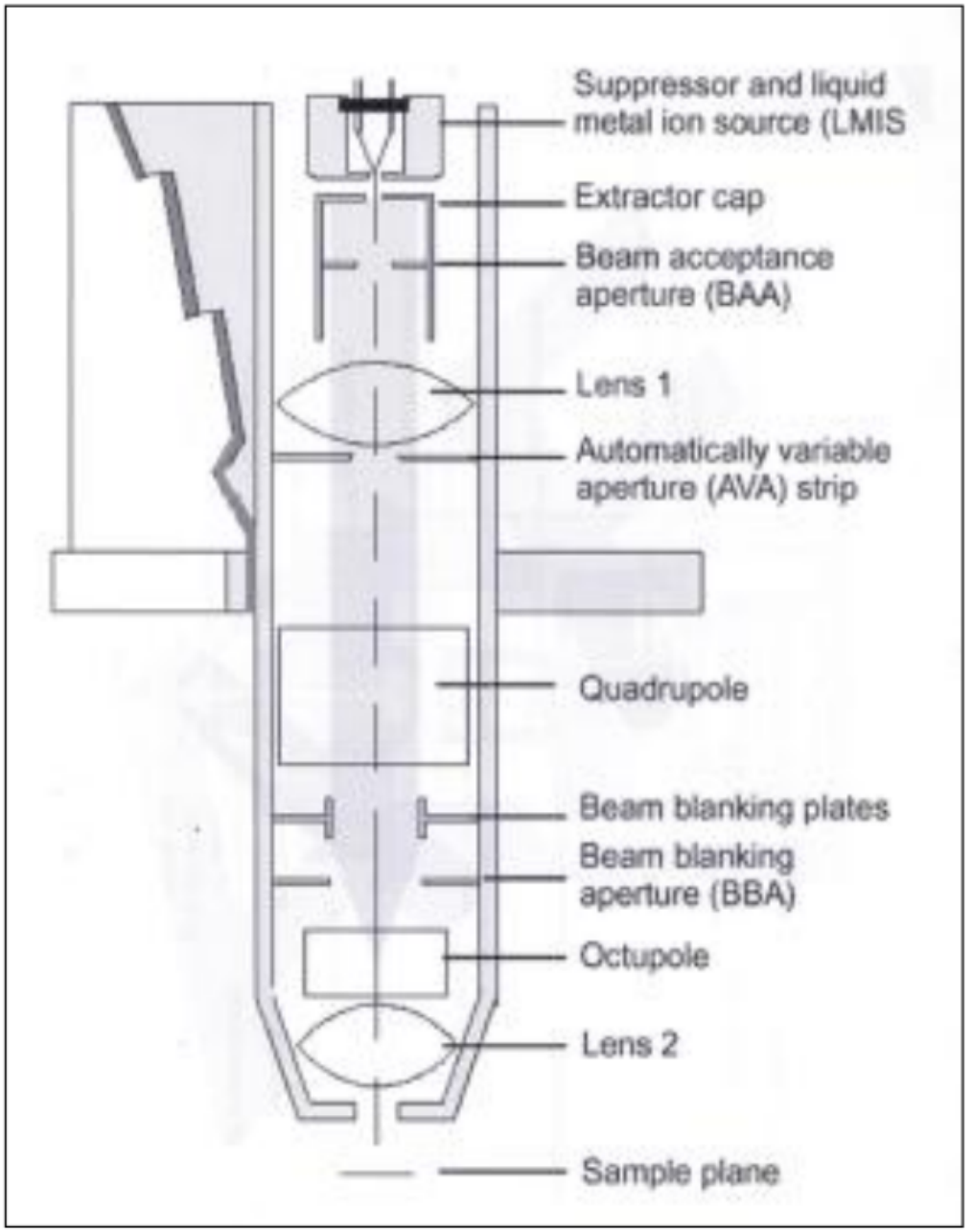
SEM





Dual beam FIB/SEM

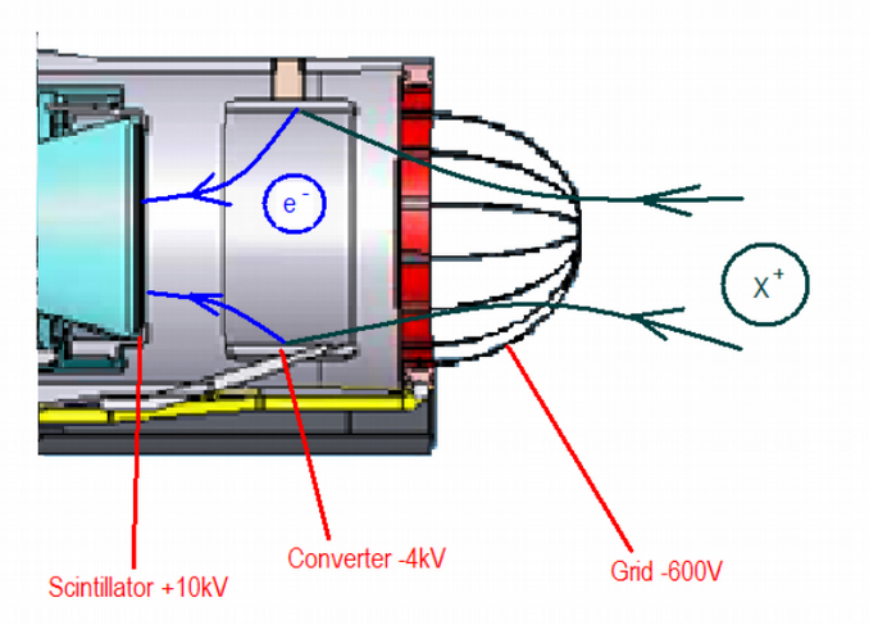


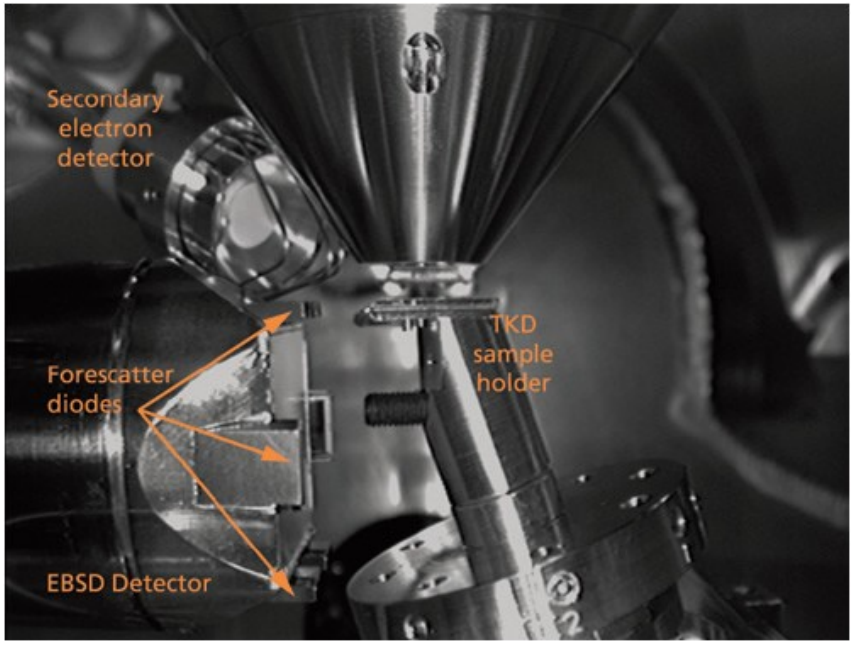


SEM - detection

- Everhart-Thornley Detector (ETD)

- Ion Convertion to Electron Detector (ICE)

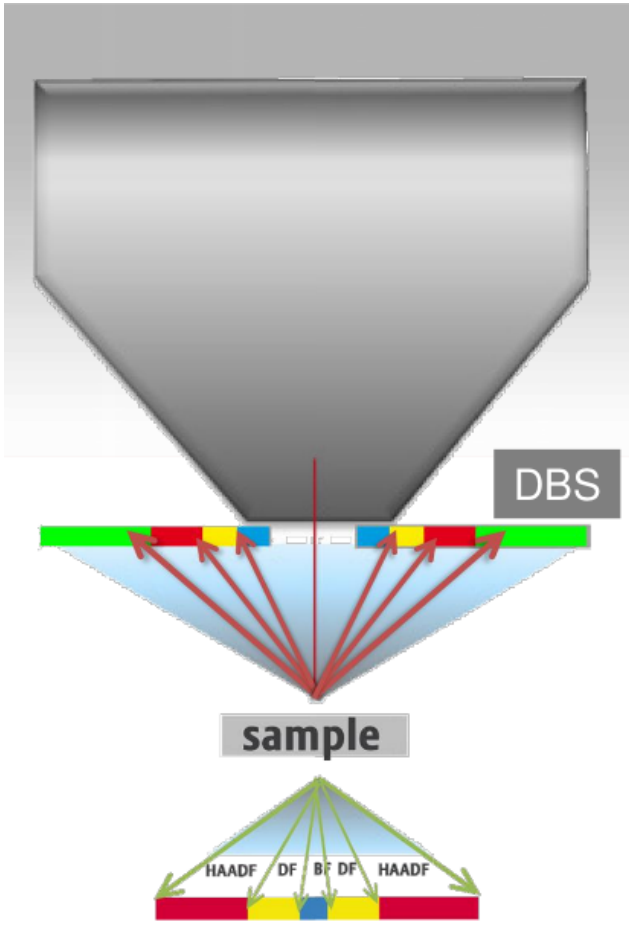




CEITEC

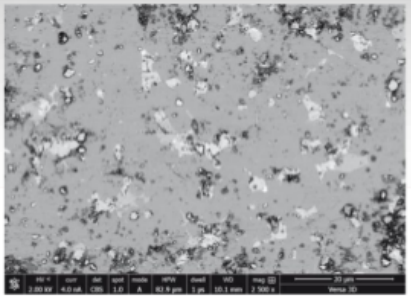
SEM - detection

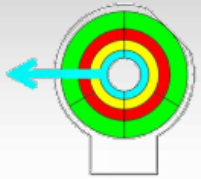
- Concentric Backscatter detector



The Directional Backscatter Electron detector* (DBS) allows collection of surface or compositional information through a Concentric Backscatter mode (CBS) to filter signal from various angles (which can be selected by segment, working distance and/or Beam Deceleration*). A range of angles can be precisely selected based on imaging conditions to reveal unique information.

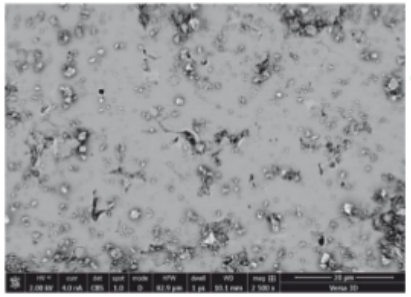
Composition and material contrast

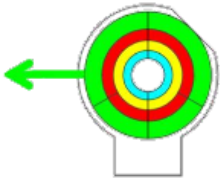




Inner rings collect signal on-axis with the primary beam which contains most channeling or atomic contrast information.

Surface information and topographic contrast





Outer rings collect large angle BSE signal, containing mostly topographic information